CENESAS

RA4E1 Group

Renesas Microcontrollers

Datasheet

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Leading-performance 100 MHz Arm Cortex-M33 core, up to 512 KB code flash memory with background operation, 8 KB Data flash memory, and 128 KB SRAM with Parity. High-integration with USB 2.0 Full-Speed, Quad SPI, and advanced analog.

Features

Arm[®] Cortex[®]-M33 Core

- Armv8-M architecture with the main extension
- Maximum operating frequency: 100 MHz
- Arm Memory Protection Unit (Arm MPU)
 - Protected Memory System Architecture (PMSAv8)
 Secure MPU (MPU_S): 8 regions
- Non-secure MPU (MPU_NS): 8 regions
- SysTick timer
 - Embeds two Systick timers: Secure and Non-secure instance
- Driven by LOCO or system clock
 CoreSight[™] ETM-M33

Memory

- Up to 512-KB code flash memory
- 8-KB data flash memory (100,000 program/erase (P/E) cycles)
- 128-KB SRAM

Connectivity

- Serial Communications Interface (SCI) × 4
- Asynchronous interfaces
- 8-bit clock synchronous interface Smart card interface
- Simple IIC
- Simple SPI
- Manchester coding (SCI3, SCI4)
- I²C bus interface (IIC)
 Serial Peripheral Interface (SPI)
- Quad Serial Peripheral Interface (QSPI)
 USB 2.0 Full-Speed Module (USBFS)
- Control Area Network module (CAN)

Analog

- 12-bit A/D Converter (ADC12)
- 12-bit D/A Converter (DAC12)

Timers

- General PWM Timer 32-bit (GPT32) × 2
- General PWM Timer 16-bit (GPT16) × 2
- Low Power Asynchronous General Purpose Timer (AGT) × 5

Security and Encryption

- Arm[®] TrustZone[®]
- Up to three regions for the code flash
- Up to two regions for the data flash
- Up to three regions for the SRAM
- Individual secure or non-secure security attribution for each peripheral

System and Power Management

- Low power modes
- Battery backup function (VBATT)
- Realtime Clock (RTC) with calendar and VBATT support
 Event Link Controller (ELC)
- Data Transfer Controller (DTC)
 DMA Controller (DMAC) × 8
- Power-on reset
- Low Voltage Detection (LVD) with voltage settings .
- Watchdog Timer (WDT)
- Independent Watchdog Timer (IWDT)

Multiple Clock Sources

- Main clock oscillator (MOSC) (8 to 24 MHz)
 Sub-clock oscillator (SOSC) (32.768 kHz)
 High-speed on-chip oscillator (HOCO) (16/18/20 MHz)
 Middle-speed on-chip oscillator (MOCO) (8 MHz)
 Low-speed on-chip oscillator (LOCO) (32.768 kHz)
 WDT L L and L

- IWDT-dedicated on-chip oscillator (15 kHz)
 Clock trim function for HOCO/MOCO/LOCO
 PLL/PLL2
- Clock out support

RENESAS

- General-Purpose I/O Ports
 - 5-V tolerance, open drain, input pull-up, switchable driving ability
- Operating Voltage
 - VCC: 2.7 to 3.6 V
- Operating Temperature and Packages
 - Ta = -40°C to +85°C
 - 64-pin LQFP (10 mm × 10 mm, 0.5 mm pitch)
 - 48-pin QFN (7 mm × 7 mm, 0.5 mm pitch)

1. Overview

The MCU integrates multiple series of software- and pin-compatible Arm[®]-based 32-bit cores that share a common set of Renesas peripherals to facilitate design scalability and efficient platform-based product development.

The MCU in this series incorporates a high-performance Arm Cortex[®]-M33 core running up to 100 MHz with the following features:

- Up to 512 KB code flash memory
- 128 KB SRAM
- Quad Serial Peripheral Interface (QSPI)
- USBFS
- Analog peripherals
- Security and safety features

1.1 Function Outline

Regarding Security function, only the access control circuit, random number generation circuit, and unique ID are supported. The operation of the other circuits is not guaranteed.

Table 1.1 Arm core

Feature	Functional description
Arm Cortex-M33 core	 Maximum operating frequency: up to 100 MHz Arm Cortex-M33 core: Armv8-M architecture with security extension Revision: r0p4-00rel0 Arm Memory Protection Unit (Arm MPU) Protected Memory System Architecture (PMSAv8) Secure MPU (MPU_S): 8 regions Non-secure MPU (MPU_NS): 8 regions SysTick timer Embeds two Systick timers: Secure and Non-secure instance Driven by SysTick timer clock (SYSTICCLK) or system clock (ICLK)

Table 1.2 Memory

Feature	Functional description
Code flash memory	Maximum 512 KB of code flash memory.
Data flash memory	8 KB of data flash memory.
Option-setting memory	The option-setting memory determines the state of the MCU after a reset.
SRAM	On-chip high-speed SRAM with or without parity bit.

Table 1.3 System (1 of 2)

Feature	Functional description
Operating modes	Two operating modes: Single-chip mode SCI/USB boot mode
Resets	The MCU provides 13 resets.
Low Voltage Detection (LVD)	The Low Voltage Detection (LVD) module monitors the voltage level input to the VCC pin. The detection level can be selected by register settings. The LVD module consists of three separate voltage level detectors (LVD0, LVD1, LVD2). LVD0, LVD1, and LVD2 measure the voltage level input to the VCC pin. LVD registers allow your application to configure detection of VCC changes at various voltage thresholds.



Table 1.3 System (2 of 2)

Feature	Functional description
Clocks	 Main clock oscillator (MOSC) Sub-clock oscillator (SOSC) High-speed on-chip oscillator (HOCO) Middle-speed on-chip oscillator (MOCO) Low-speed on-chip oscillator (LOCO) IWDT-dedicated on-chip oscillator PLL/PLL2 Clock out support
Clock Frequency Accuracy Measurement Circuit (CAC)	The Clock Frequency Accuracy Measurement Circuit (CAC) counts pulses of the clock to be measured (measurement target clock) within the time generated by the clock selected as the measurement reference (measurement reference clock), and determines the accuracy depending on whether the number of pulses is within the allowable range. When measurement is complete or the number of pulses within the time generated by the measurement reference clock is not within the allowable range, an interrupt request is generated.
Interrupt Controller Unit (ICU)	The Interrupt Controller Unit (ICU) controls which event signals are linked to the Nested Vector Interrupt Controller (NVIC), the DMA Controller (DMAC), and the Data Transfer Controller (DTC) modules. The ICU also controls non-maskable interrupts.
Low power modes	Power consumption can be reduced in multiple ways, including setting clock dividers, stopping modules, selecting power control mode in normal operation, and transitioning to low power modes.
Battery backup function	A battery backup function is provided for partial powering by a battery. The battery-powered area includes the RTC, SOSC, backup memory, and switch between VCC and VBATT.
Register write protection	The register write protection function protects important registers from being overwritten due to software errors. The registers to be protected are set with the Protect Register (PRCR).
Memory Protection Unit (MPU)	The MCU has one Memory Protection Unit (MPU).

Table 1.4 Event link

Feature	Functional description
	The Event Link Controller (ELC) uses the event requests generated by various peripheral modules as source signals to connect them to different modules, allowing direct link between the modules without CPU intervention.

Table 1.5 Direct memory access

Feature	Functional description
Data Transfer Controller (DTC)	A Data Transfer Controller (DTC) module is provided for transferring data when activated by an interrupt request.
	The MCU includes an 8-channel direct memory access controller (DMAC) that can transfer data without intervention from the CPU. When a DMA transfer request is generated, the DMAC transfers data stored at the transfer source address to the transfer destination address.

Table 1.6 External bus interface

Feature	Functional description
External bus	QSPI area (EQBIU): Connected to the QSPI (external device interface)

Table 1.7 Timers (1 of 2)

Feature	Functional description
General PWM Timer (GPT)	The General PWM Timer (GPT) is a 32-bit timer with GPT32 × 2 channels and a 16-bit timer with GPT16 × 2 channels. PWM waveforms can be generated by controlling the up-counter, down-counter, or the up- and down-counter. The GPT can also be used as a general-purpose timer.
Port Output Enable for GPT (POEG)	The Port Output Enable (POEG) function can place the General PWM Timer (GPT) output pins in the output disable state



Table 1.7 Timers (2 of 2)

Feature	Functional description
Low Power Asynchronous General Purpose Timer (AGT)	The Low Power Asynchronous General Purpose Timer (AGT) is a 16-bit timer that can be used for pulse output, external pulse width or period measurement, and counting external events. This timer consists of a reload register and a down counter. The reload register and the down counter are allocated to the same address, and can be accessed with the AGT register.
Realtime Clock (RTC)	The realtime clock (RTC) has two counting modes, calendar count mode and binary count mode, that are used by switching register settings. For calendar count mode, the RTC has a 100-year calendar from 2000 to 2099 and automatically adjusts dates for leap years. For binary count mode, the RTC counts seconds and retains the information as a serial value. Binary count mode can be used for calendars other than the Gregorian (Western) calendar.
Watchdog Timer (WDT)	The Watchdog Timer (WDT) is a 14-bit down counter that can be used to reset the MCU when the counter underflows because the system has run out of control and is unable to refresh the WDT. In addition, the WDT can be used to generate a non-maskable interrupt or an underflow interrupt.
Independent Watchdog Timer (IWDT)	The Independent Watchdog Timer (IWDT) consists of a 14-bit down counter that must be serviced periodically to prevent counter underflow. The IWDT provides functionality to reset the MCU or to generate a non-maskable interrupt or an underflow interrupt. Because the timer operates with an independent, dedicated clock source, it is particularly useful in returning the MCU to a known state as a fail-safe mechanism when the system runs out of control. The IWDT can be triggered automatically by a reset, underflow, refresh error, or a refresh of the count value in the registers.

Table 1.8 Communication interfaces

Feature	Functional description
Serial Communications Interface (SCI)	 The Serial Communications Interface (SCI) × 4 channels have asynchronous and synchronous serial interfaces: Asynchronous interfaces (UART and Asynchronous Communications Interface Adapter (ACIA)) 8-bit clock synchronous interface Simple IIC (master-only) Simple SPI Smart card interface Manchester interface The smart card interface complies with the ISO/IEC 7816-3 standard for electronic signals and transmission protocol. SCIn (n = 0, 3, 4, 9) has FIFO buffers to enable continuous and full-duplex communication, and the data transfer speed can be configured independently using an on-chip baud rate generator.
I ² C bus interface (IIC)	The I ² C bus interface (IIC) has 1 channel. The IIC module conforms with and provides a subset of the NXP I ² C (Inter-Integrated Circuit) bus interface functions.
Serial Peripheral Interface (SPI)	The Serial Peripheral Interface (SPI) has 1 channel. The SPI provides high-speed full-duplex synchronous serial communications with multiple processors and peripheral devices.
Control Area Network (CAN)	The Controller Area Network (CAN) module uses a message-based protocol to receive and transmit data between multiple slaves and masters in electromagnetically noisy applications. The module complies with the ISO 11898-1 (CAN 2.0A/CAN 2.0B) standard and supports up to 32 mailboxes, which can be configured for transmission or reception in normal mailbox and FIFO modes. Both standard (11-bit) and extended (29-bit) messaging formats are supported. The CAN module requires an additional external CAN transceiver.
USB 2.0 Full-Speed module (USBFS)	The USB 2.0 Full-Speed module (USBFS) can operate as a host controller or device controller. The module supports full-speed and low-speed (host controller only) transfer as defined in Universal Serial Bus Specification 2.0. The module has an internal USB transceiver and supports all of the transfer types defined in Universal Serial Bus Specification 2.0. The USB has buffer memory for data transfer, providing a maximum of 10 pipes. Pipes 1 to 9 can be assigned any endpoint number based on the peripheral devices used for communication or based on your system.
Quad Serial Peripheral Interface (QSPI)	The Quad Serial Peripheral Interface (QSPI) is a memory controller for connecting a serial ROM (nonvolatile memory such as a serial flash memory, serial EEPROM, or serial FeRAM) that has an SPI-compatible interface.



Table 1.9 Analog

Feature	Functional description
12-bit A/D Converter (ADC12)	A 12-bit successive approximation A/D converter is provided. Up to 9 analog input channels are selectable.
12-bit D/A Converter (DAC12)	A 12-bit D/A converter (DAC12) is provided.

Table 1.10 Data processing

Feature	Functional description
Cyclic Redundancy Check (CRC) calculator	The Cyclic Redundancy Check (CRC) generates CRC codes to detect errors in the data. The bit order of CRC calculation results can be switched for LSB-first or MSB-first communication. Additionally, various CRC-generation polynomials are available.
Data Operation Circuit (DOC)	The Data Operation Circuit (DOC) compares, adds, and subtracts 16-bit data. When a selected condition applies, 16-bit data is compared and an interrupt can be generated.

Table 1.11 I/O ports

Feature	Functional description
Programmable I/O ports	 I/O ports for the 64-pin LQFP I/O pins: 43 Input pins: 1 Pull-up resistors: 44 N-ch Open-drain outputs: 43 5-V tolerance: 9 I/O ports for the 48-pin QFN I/O pins: 29 Input pins: 1 Pull-up resistors: 30 N-ch Open-drain outputs: 29 5-V tolerance: 4



1.2 Block Diagram

Figure 1.1 shows a block diagram of the MCU superset. Some individual devices within the group have a subset of the features.



Figure 1.1 Block diagram

1.3 Part Numbering

Figure 1.2 shows the product part number information, including memory capacity and package type. Table 1.12 shows a list of products.





Note: Check the order screen for each product on the Renesas website for valid symbols after the #.

Figure 1.2 Part numbering scheme

Table 1.12 Product list

Product part number	Package code	Code flash	Data flash	SRAM	Operating temperature
R7FA4E10D2CFM	PLQP0064KB-C	512 KB	8 KB	128 KB	-40 to +85°C
R7FA4E10D2CNE	PWQN0048KC-A				
R7FA4E10B2CFM	PLQP0064KB-C	256 KB	8 KB	128 KB	-40 to +85°C
R7FA4E10B2CNE	PWQN0048KC-A				



Function Comparison 1.4

Table 1.13 **Function Comparison**

Parts number		R7FA4E10D2CFM R7FA4E10B2CFM	R7FA4E10D2CNE R7FA4E10B2CNE	
Pin count		64	48	
Package		LQFP	QFN	
Code flash memory			2KB 6KB	
Data flash memory		8	КВ	
SRAM		12	8 KB	
	Parity	64	k KB	
Standby SRAM		1	КВ	
DMA	DTC	Y	/es	
	DMAC		8	
System	CPU clock	100 MH	Ηz (max.)	
	CPU clock sources	MOSC, SOSC, HOC	O, MOCO, LOCO, PLL	
	CAC	Y	/es	
	WDT/IWDT	Y	/es	
	Backup register	12	28 B	
Communication	SCI ^{*1}	4		
	IIC		1	
	SPI		1	
	CAN		1	
	USBFS	Y	/es	
	QSPI	Yes		
Timers	GPT32 ^{*1}		2	
	GPT16 ^{*1}		2	
	AGT ^{*1}		5	
	RTC	Υ	/es	
Analog	ADC12	9	7	
5	DAC12		1	
Data processing	CRC		/es	
1 0	DOC		/es	
Event control	ELC	Yes		
Security			d Lifecycle management	
I/O ports	I/O pins	43	29	
	Input pins	1	1	
	Pull-up resistors	44	30	
	N-ch Open-drain outputs	43	29	
	5-V tolerance	9	4	

Note 1. Available pins depend on the Pin count, about details see section 1.7. Pin Lists. Note 2. Only access control circuit, random number generation circuit, and unique ID are supported. The operation of other circuits is not guaranteed.



Table 1.14Pin functions (1 of 3)

Function	Signal	I/O	Description
Power supply	VCC	Input	Power supply pin. Connect it to the system power supply. Connect this pin to VSS by a 0.1- μ F capacitor. The capacitor should be placed close to the pin.
	VCL	I/O	Connect this pin to the VSS pin by the smoothing capacitor used to stabilize the internal power supply. Place the capacitor close to the pin.
	VBATT	Input	Battery Backup power pin
	VSS	Input	Ground pin. Connect it to the system power supply (0 V).
Clock	XTAL	Output	Pins for a crystal resonator. An external clock signal can be input
	EXTAL	Input	through the EXTAL pin.
	XCIN	Input	Input/output pins for the sub-clock oscillator. Connect a crystal
	XCOUT	Output	resonator between XCOUT and XCIN.
	CLKOUT	Output	Clock output pin
Operating mode control	MD	Input	Pin for setting the operating mode. The signal level on this pin must not be changed during operation mode transition on release from the reset state.
System control	RES	Input	Reset signal input pin. The MCU enters the reset state when this signal goes low.
CAC	CACREF	Input	Measurement reference clock input pin
On-chip emulator	TMS	I/O	On-chip emulator or boundary scan pins
	TDI	Input	
	ТСК	Input	
	TDO	Output	
	SWO	Output	Serial wire trace output pin
	SWDIO	I/O	Serial wire debug data input/output pin
	SWCLK	Input	Serial wire clock pin
Interrupt	NMI	Input	Non-maskable interrupt request pin
	IRQn	Input	Maskable interrupt request pins
	IRQn-DS	Input	Maskable interrupt request pins that can also be used in Deep Software Standby mode
GPT	GTETRGA, GTETRGB, GTETRGC, GTETRGD	Input	External trigger input pins
	GTIOCnA, GTIOCnB	I/O	Input capture, output compare, or PWM output pins
AGT	AGTEEn	Input	External event input enable signals
	AGTIOn	I/O	External event input and pulse output pins
	AGTOn	Output	Pulse output pins
	AGTOAn	Output	Output compare match A output pins
	AGTOBn	Output	Output compare match B output pins
RTC	RTCOUT	Output	Output pin for 1-Hz or 64-Hz clock
	RTCICn	Input	Time capture event input pins



Table 1.14Pin functions (2 of 3)

Function	Signal	I/O	Description
SCI	SCKn	I/O	Input/output pins for the clock (clock synchronous mode)
	RXDn	Input	Input pins for received data (asynchronous mode/clock synchronous mode)
	TXDn	Output	Output pins for transmitted data (asynchronous mode/clock synchronous mode)
	CTSn_RTSn	I/O	Input/output pins for controlling the start of transmission and reception (asynchronous mode/clock synchronous mode), active-low.
	CTSn	Input	Input for the start of transmission.
	SCLn	I/O	Input/output pins for the IIC clock (simple IIC mode)
	SDAn	I/O	Input/output pins for the IIC data (simple IIC mode)
	SCKn	I/O	Input/output pins for the clock (simple SPI mode)
	MISOn	I/O	Input/output pins for slave transmission of data (simple SPI mode)
	MOSIn	I/O	Input/output pins for master transmission of data (simple SPI mode)
	SSn	Input	Chip-select input pins (simple SPI mode), active-low
IIC	SCLn	I/O	Input/output pins for the clock
	SDAn	I/O	Input/output pins for data
SPI	RSPCKA	I/O	Clock input/output pin
	MOSIA	I/O	Input or output pins for data output from the master
	MISOA	I/O	Input or output pins for data output from the slave
	SSLA0	I/O	Input or output pin for slave selection
	SSLA1 to SSLA3	Output	Output pins for slave selection
CAN	CRXn	Input	Receive data
	CTXn	Output	Transmit data
USBFS	VCC_USB	Input	Power supply pin
	VSS_USB	Input	Ground pin
	USB_DP	I/O	D+ pin of the USB on-chip transceiver. Connect this pin to the D+ pin of the USB bus.
	USB_DM	I/O	D- pin of the USB on-chip transceiver. Connect this pin to the D- pin of the USB bus.
	USB_VBUS	Input	USB cable connection monitor pin. Connect this pin to VBUS of the USB bus. The VBUS pin status (connected or disconnected) can be detected when the USB module is operating as a function controller.
	USB_VBUSEN	Output	VBUS (5 V) supply enable signal for external power supply chip
	USB_OVRCURA-DS	Input	Overcurrent pins for USBFS that can also be used in Deep Software Standby mode. Connect the external overcurrent detection signals to these pins.
QSPI	QSPCLK	Output	QSPI clock output pin
	QSSL	Output	QSPI slave output pin
	QIO0 to QIO3	I/O	Data0 to Data3



Table 1.14Pin functions (3 of 3)

Function	Signal	I/O	Description
Analog power supply	AVCC0	Input	Analog voltage supply pin. This is used as the analog power supply for the respective modules. Supply this pin with the same voltage as the VCC pin.
	AVSS0	Input	Analog ground pin. This is used as the analog ground for the respective modules. Supply this pin with the same voltage as the VSS pin.
	VREFH	Input	Analog reference voltage supply pin for the D/A Converter. Connect this pin to AVCC0 when not using the D/A Converter.
	VREFL	Input	Analog reference ground pin for the D/A Converter. Connect this pin to AVSS0 when not using the D/A Converter.
	VREFH0	Input	Analog reference voltage supply pin for the ADC12. Connect this pin to AVCC0 when not using the ADC12.
	VREFL0	Input	Analog reference ground pin for the ADC12. Connect this pin to AVSS0 when not using the ADC12.
ADC12	ANmn	Input	Input pins for the analog signals to be processed by the A/D converter. (m: ADC unit number, n: pin number)
	ADTRGm	Input	Input pins for the external trigger signals that start the A/D conversion, active-low.
DAC12	DAn	Output	Output pins for the analog signals processed by the D/A converter.
I/O ports	Pmn	I/O	General-purpose input/output pins (m: port number, n: pin number)
	P200	Input	General-purpose input pin



1.6 Pin Assignments

The following figures show the pin assignments from the top view.



Figure 1.3 Pin assignment for LQFP 64-pin



Figure 1.4 Pin assignment for QFN 48-pin





Figure 1.5 Pin assignment for BGA 64-pin (top view, pad side down)



1. Overview

1.7 Pin Lists

Table 1.15Pin list (1 of 2)

LQFP64	QFN48	Power, System, Clock, Debug, CAC	I/O ports	Ex. Interrupt	SCI/IIC/SPI/CAN/USBFS/QSPI	GPT/AGT/RTC	ADC12/DAC12
1	_	_	P400	IRQ0	SCK4/SCL0_A	AGTIO1	_
2	_	_	P401	IRQ5-DS	CTS4 RTS4/SS4/SDA0 A/CTX0	GTETRGA	_
3	1	CACREF	P402	IRQ4-DS	 CTS4/CRX0	AGTIO0/AGTIO1/AGTIO2/AGTIO3/RTCIC0	_
4	2	VBATT	_	_	_	_	_
5	3	VCL	_	_		_	_
6	4	XCIN	_	_			_
7	5	XCOUT		_		_	
8	6	VSS	_	_		_	_
9	7	XTAL	P213	IRQ2		GTETRGC/AGTEE2	
	7 8		P213	IRQ3	_		_
10		EXTAL	PZ1Z			GTETRGD/AGTEE1	-
11	9	VCC	_	-	_	-	-
12	-	_	P411	IRQ4	TXD0/MOSI0/SDA0/CTS3_RTS3/SS3	AGTOA1	-
13	-	_	P410	IRQ5	RXD0/MISO0/SCL0/SCK3	AGTOB1	-
14	10	-	P409	IRQ6	TXD3/MOSI3/SDA3	AGTOA2	-
15	11	_	P408	IRQ7	CTS4/RXD3/MISO3/SCL3/SCL0_B	AGTOB2	-
16	12	_	P407	—	CTS4_RTS4/SS4/SDA0_B/USB_VBUS	AGTIO0/RTCOUT	ADTRG0
17	13	VSS_USB	—	-	_	_	-
18	14	USB_DM	-	—	_	_	-
19	15	USB_DP	-	_	_	-	-
20	16	VCC_USB	—	—	_	-	-
21	17	_	P207	_	TXD4/MOSI4/SDA4/QSSL	—	-
22	18	_	P206	IRQ0-DS	RXD4/MISO4/SCL4/CTS9/USB_VBUSEN	_	_
23	—	CLKOUT	P205	IRQ1-DS	TXD4/MOSI4/SDA4/CTS9_RTS9/SS9/USB_OVRCURA-DS	GTIOC4A/AGTO1	_
24	-	_	P208	_	QIO3	_	_
25	19	RES	_	_	_	_	—
26	20	MD	P201	_	_	_	_
27	21	_	P200	NMI	_	_	_
28	_	_	P304	IRQ9	_	AGTEE2	_
29	_	_	P303	_	CTS9	_	_
30	22	_	P302	IRQ5	SSLA3	GTIOC4A	_
31	23	_	P301	IRQ6	CTS9 RTS9/SS9/SSLA2	GTIOC4B/AGTIO0	_
32	24	TCK/SWCLK	P300	_	SSLA1		_
33	25	TMS/SWDIO	P108	_	CTS9_RTS9/SS9/SSLA0	AGTOA3	_
34	26	TDO/SWO/CLKOUT	P109	_	TXD9/MOSI9/SDA9/MOSIA	GTIOC1A/AGTOB3	_
35	27	TDI	P110	IRQ3	RXD9/MISO9/SCL9/MISOA	GTIOC1B/AGTEE3	_
36	28	_	P111	IRQ4	SCK9/RSPCKA	AGTOA5	_
37	29	_	P112	_	SSLA0/QSSL	AGTOB5	_
37	23	_	P112	_			
38 39		- VCC	-	_		GTIOC2A/AGTEE5	_
40	31	VSS		_	_		-
41	-	_	P107	_		AGTOA0	—
42	-	-	P106	-	_	AGTOB0	-
43	-	_	P105	IRQ0	_	GTETRGA/GTIOC1A/AGTO2	-
44	32	_	P104	IRQ1	QIO2	GTETRGB/GTIOC1B/AGTEE2	-
45	33	_	P103	-	CTS0_RTS0/SS0/CTX0/QIO3	GTIOC2A/AGTIO2	-
46	34	_	P102	-	SCK0/CRX0/QIO0	GTIOC2B/AGTO0	ADTRG0
47	35	-	P101	IRQ1	TXD0/MOSI0/SDA0/QIO1	GTETRGB/GTIOC5A/AGTEE0	-



LQFP64	QFN48	Power, System, Clock, Debug, CAC	I/O ports	Ex. Interrupt	SCI/IIC/SPI/CAN/USBFS/QSPI	GPT/AGT/RTC	ADC12/DAC12
48	36	—	P100	IRQ2	RXD0/MISO0/SCL0/QSPCLK	GTETRGA/GTIOC5B/AGTIO0	-
49	37	CACREF	P500	_	USB_VBUSEN/QSPCLK	AGTOA0	AN016
50	-	VCC	-	_	_	-	-
51	-	VSS	-	_	_	-	-
52	38	_	P015	IRQ13	_	_	AN013
53	39	—	P014	_	_	-	AN012/DA0
54	40	—	P013	_	_	-	AN011
55	41	VREFH	_	_	_	-	-
56	42	AVCC0	—	_	_	-	_
57	43	AVSS0/VREFL	_	_	_	-	-
58	44	VREFL0	_	_	_	-	-
59	45	VREFH0	_	_	_	-	-
60	-	_	P004	IRQ9-DS	_	-	AN004
61	—	_	P003	_	_	_	AN003
62	46	_	P002	IRQ8-DS	_	_	AN002
63	47	_	P001	IRQ7-DS	_	_	AN001
64	48	_	P000	IRQ6-DS	_	-	AN000

Table 1.15 Pin list (2 of 2)

Note: Several pin names have the added suffix of _A, _B, _C, _D, _E, and _F. The suffix can be ignored when assigning functionality.



2. Electrical Characteristics

Supported peripheral functions and pins differ from one product name to another.

Unless otherwise specified, the electrical characteristics of the MCU are defined under the following conditions:

- VCC = AVCC0 = VCC_USB = VBATT = 2.7 to 3.6 V
- $2.7 \leq VREFH0/VREFH \leq AVCC0$
- VSS = AVSS0 = VREFL0/VREFL = VSS_USB = 0 V
- $T_a = T_{opr}$

Figure 2.1 shows the timing conditions.



Figure 2.1 Input or output timing measurement conditions

The recommended measurement conditions for the timing specification of each peripheral provided are for the best peripheral operation. Make sure to adjust the driving abilities of each pin to meet your conditions.

2.1 Absolute Maximum Ratings

Table 2.1 Absolute maximum ratings

Parameter	Symbol	Value	Unit
Power supply voltage	VCC, VCC_USB ^{*2}	-0.3 to +4.0	V
VBATT power supply voltage	VBATT	-0.3 to +4.0	V
Input voltage (except for 5 V-tolerant ports ^{*1})	V _{in}	-0.3 to VCC + 0.3	V
Input voltage (5 V-tolerant ports ^{*1})	V _{in}	-0.3 to + VCC + 4.0 (max. 5.8)	V
Reference power supply voltage	VREFH/VREFH0	-0.3 to VCC + 0.3	V
Analog power supply voltage	AVCC0 ^{*2}	-0.3 to +4.0	V
Analog input voltage	V _{AN}	-0.3 to AVCC0 + 0.3	V
Operating temperature*3 *4	T _{opr}	-40 to +85	°C
Storage temperature	T _{stg}	-55 to +125	°C

Note 1. Ports P205, P206, P400, P401, and P407 to P411 are 5 V tolerant.

Note 2. Connect AVCC0 and VCC_USB to VCC.

Note 3. See section 2.2.1. Tj/Ta Definition.

Note 4. Contact a Renesas Electronics sales office for information on derating operation when Ta = +85°C. Derating is the systematic reduction of load for improved reliability.



Caution: Permanent damage to the MCU might result if absolute maximum ratings are exceeded.

Table 2.2	Recommended operating conditions
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Parameter	Symbol	Value	Min	Тур	Max	Unit
Power supply voltages	VCC	When USB is not used	2.7	—	3.6	V
		When USB is used	3.0	—	3.6	V
	VSS		—	0	—	V
USB power supply voltages	VCC_USB		—	VCC	—	V
	VSS_USB		—	0	—	V
VBATT power supply voltage	VBATT		1.65 ^{*2}	_	3.6	V
Analog power supply voltages	AVCC0*1		—	VCC	—	V
	AVSS0		—	0	—	V

Note 1. Connect AVCC0 to VCC. When the A/D converter and the D/A converter are not in use, do not leave the AVCC0, VREFH/VREFH0, AVSS0, and VREFL/VREFL0 pins open. Connect the AVCC0 and VREFH/VREFH0 pins to VCC, and the AVSS0 and VREFL/VREFL0 pins to VSS, respectively.

Note 2. Low CL crystal cannot be used below VBATT = 1.8V.

2.2 DC Characteristics

2.2.1 Tj/Ta Definition

Table 2.3 DC characteristics

Conditions: Products with operating temperature (T_a) -40 to +85°C

Parameter	Symbol	Тур	Мах	Unit	Test conditions
Permissible junction temperature	Tj	_	105	°C	High-speed mode Low-speed mode Subosc-speed mode

Note: Make sure that $T_j = T_a + \theta ja \times \text{total power consumption}$ (W), where total power consumption = (VCC - V_{OH}) × $\Sigma I_{OH} + V_{OL} \times \Sigma I_{OL} + I_{CC} \text{max} \times \text{VCC}$.

2.2.2 I/O V_{IH}, V_{IL}

Table 2.4 I/O V_{IH}, V_{IL} (1 of 2)

Parameter	Parameter			Min	Тур	Мах	Unit
Input voltage (except for Schmitt trigger input pins)		EXTAL (external clock input), SPI (except RSPCK)	VIH	VCC × 0.8	—	_	V
		VIL	_	—	VCC × 0.2		
		IIC (SMBus)	V _{IH}	2.1		VCC + 3.6 (max 5.8)	
			V _{IL}	_	—	0.8	



Table 2.4 I/O V_{IH}, V_{IL} (2 of 2)

Parameter					Symbol	Min	Тур	Max	Uni
Schmitt trigger input voltage	Peripheral function pin	IIC (exce	ept for SMBus)		V _{IH}	VCC × 0.7	-	VCC + 3.6 (max 5.8)	V
					V _{IL}	—	-	VCC × 0.3	1
				ΔV _T	VCC × 0.05	-	_		
		5 V-toler	ant ports ^{*1 *5}		V _{IH}	VCC × 0.8	—	VCC + 3.6 (max 5.8)	1
					VIL	—	-	VCC × 0.2]
				ΔV _T	VCC × 0.05	—	_		
		RTCIC0	Battery Backup Function power supply is selected When VCC power	power supply is	V _{IH}	V _{BATT} × 0.8	-	V _{BATT} + 0.3	
				selected	V _{IL}	—	-	V _{BATT} × 0.2	1
				ΔV _T	V _{BATT} × 0.05	-	_		
				When VCC power supply is selected	V _{IH}	VCC × 0.8	—	Higher voltage either VCC + 0.3 V or V _{BATT} + 0.3 V	
				V _{IL}	—	-	VCC × 0.2	1	
					ΔV _T	VCC × 0.05	-	_	-
			When not using the Battery Backup		VIH	VCC × 0.8	-	VCC + 0.3	1
			Function		VIL	_	-	VCC × 0.2	1
					ΔV _T	VCC × 0.05	-	_	-
		Other in	out pins ^{*2}		V _{IH}	VCC × 0.8	-	_	1
					V _{IL}	—	-	VCC × 0.2	1
					ΔV _T	VCC × 0.05	-	_	1
	Ports	5 V-toler	lerant ports ^{*3 *5}		V _{IH}	VCC × 0.8	-	VCC + 3.6 (max 5.8)	V
					VIL	—	-	VCC × 0.2]
		Other in	out pins ^{*4}	VIH	VCC × 0.8	—	—	1	
					VIL	_	_	VCC × 0.2	1

Note 1. RES and peripheral function pins associated with Ports P205, P206, P400, P401, and P407 to P411 (total 10 pins).

Note 2. All input pins except for the peripheral function pins already described in the table.

Note 3. Ports P205, P206, P400, P401, and P407 to P411 (total 9 pins).

Note 4. All input pins except for the ports already described in the table. Note 5. When VCC is less than 2.7 V, the input voltage of 5 V-tolerant ports should be less than 3.6 V, otherwise breakdown may occur because 5 V-tolerant ports are electrically controlled so as not to violate the break down voltage.



2.2.3 I/O I_{OH}, I_{OL}

Table 2.5 I/O I_{OH}, I_{OL}

Parameter			Symbol	Min	Тур	Мах	Unit
Permissible output current (average value per	Ports P000 to P004, P013 to P015,	_	I _{OH}	—	—	-2.0	mA
pin)	P201		I _{OL}	—	—	2.0	mA
	Ports P205, P206, P407 to P411 (total	Low drive ^{*1}	I _{OH}	—	—	-2.0	mA
	7 pins)		I _{OL}	—	—	2.0	mA
		Middle drive ^{*2}	I _{OH}	—	—	-4.0	mA
			I _{OL}	—	—	4.0	mA
		High drive ^{*3}	I _{OH}	—	—	-20	mA
			I _{OL}	—	—	20	mA
	Other output pins ^{*4}	Low drive ^{*1}	I _{OH}	—	—	-2.0	mA
			I _{OL}	—	—	2.0	mA
		Middle drive*2	I _{OH}	—	—	-4.0	mA
			I _{OL}	—	—	4.0	mA
		High drive ^{*3}	I _{ОН}	—	—	-16	mA
			I _{OL}	—	—	16	mA
Permissible output current (max value per pin)	Ports P000 to P004, P013 to P015,	—	I _{OH}	—	—	-4.0	mA
	P201		I _{OL}	—	—	4.0	mA
	Ports P205, P206, P407 to P411 (total	Low drive ^{*1}	I _{OH}	—	—	-4.0	mA
	7 pins)		I _{OL}	—	—	4.0	mA
		Middle drive ^{*2}	I _{OH}	—	—	-8.0	mA
			I _{OL}	—	—	8.0	mA
		High drive ^{*3}	I _{OH}	—	—	-40	mA
			I _{OL}	—	—	40	mA
	Other output pins ^{*4}	Low drive ^{*1}	I _{OH}	—	—	-4.0	mA
			I _{OL}	—	—	4.0	mA
		Middle drive ^{*2}	I _{ОН}	—	—	-8.0	mA
			I _{OL}	—	—	8.0	mA
		High drive ^{*3}	I _{ОН}	_	_	-32	mA
			I _{OL}		_	32	mA
Permissible output current (maxvalue of total of all pins)	Maximum of all output pins		ΣI _{OH (max)}		_	-80	mA
			$\Sigma I_{OL \ (max)}$	—	—	80	mA

Note 1. This is the value when low driving ability is selected in the Port Drive Capability bit in the PmnPFS register. The selected driving ability is retained in Deep Software Standby mode.

Note 2. This is the value when middle driving ability is selected in the Port Drive Capability bit in the PmnPFS register. The selected driving ability is retained in Deep Software Standby mode.

Note 3. This is the value when high driving ability is selected in the Port Drive Capability bit in the PmnPFS register. The selected driving ability is retained in Deep Software Standby mode.

Note 4. Except for P200, which is an input port.

Caution: To protect the reliability of the MCU, the output current values should not exceed the values in this table. The average output current indicates the average value of current measured during 100 µs.



2.2.4 I/O $V_{OH},\,V_{OL},$ and Other Characteristics

Table 2.6	I/O V_{OH} , V_{OL} , and other characteristics
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Parameter		Symbol	Min	Тур	Мах	Unit	Test conditions
Output voltage	IIC	V _{OL}	—	—	0.4	V	I _{OL} = 3.0 mA
		V _{OL}	—	_	0.6		I _{OL} = 6.0 mA
	IIC*1	V _{OL}	—	—	0.4		I _{OL} = 15.0 mA (ICFER.FMPE = 1)
		V _{OL}	—	0.4	—		I _{OL} = 20.0 mA (ICFER.FMPE = 1)
	Ports P205, P206, P407 to P411 (total 7 pins) ^{*2}	V _{OH}	VCC - 1.0	_	_		I _{OH} = -20 mA VCC = 3.3 V
		V _{OL}	_	—	1.0		I _{OL} = 20 mA VCC = 3.3 V
	Other output pins	V _{OH}	VCC - 0.5	—	—		I _{OH} = –1.0 mA
		V _{OL}	—	—	0.5		I _{OL} = 1.0 mA
Input leakage current	RES	I _{in}	_	_	5.0	μA	V _{in} = 0 V V _{in} = 5.5 V
	Port P200		_		1.0		V _{in} = 0 V V _{in} = VCC
Three-state leakage current (off state)	5 V-tolerant ports	lI _{TSI} I	_	_	5.0	μA	V _{in} = 0 V V _{in} = 5.5 V
	Other ports (except for port P200)		_	_	1.0		V _{in} = 0 V V _{in} = VCC
Input pull-up MOS current	Ports P0 to P5	Ip	-300	_	-10	μA	VCC = 2.7 to 3.6 V V _{in} = 0 V
Input capacitance	Ports P014, P015	C _{in}	_	—	16	pF	Vbias = 0 V
	USB_DP and USB_DM		_	—	12		Vamp = 20 mV f = 1 MHz
	Ports P400, P401		_	—	10		Ta = 25°C
	Other input pins		—		8		

Note 1. SCL0_A, SDA0_A (total 2 pins). Note 2. This is the value when high driving ability is selected in the Port Drive Capability bit in the PmnPFS register. The selected driving ability is retained in Deep Software Standby mode.



2.2.5 Operating and Standby Current

Table 2.7Operating and standby current (1 of 2)

Parameter					Symbol	Min	Тур	Max	Unit	Test conditions
Supply	High-speed	Maximum ^{*2 *13}			I _{CC} *3	-	-	65	mA	ICLK =
current ^{*1}	mode	CoreMark ^{®*5 *6}	12 *14		-	_	8.1	_		100 MHz PCLKA =
		Normal mode		ral clocks enabled, ode executing from		-	15.4	-	-	100 MHz PCLKB = 50 MHz PCLKC =
				ral clocks disabled, ode executing from 2 *14		-	6.1	-	_	50 MHz PCLKD = 100 MHz FCLK =
		Sleep mode ^{*5 *14}				-	4.4 ^{*6} *12	25 ^{*7} *13		50 MHz
		Increase during	Data flash	P/E		—	6	_		
		BGO operation	Code flash	P/E		—	8	—		
	Low-speed mo	ode ^{*5 *10}				—	0.8	_		ICLK = 1 MHz
	Subosc-speed	mode ^{*5 *11}				-	0.7	-		ICLK = 32.768 kHz
	Software Stan	dby mode	SNZCR.RX	(DREQEN = 1		—	—	14		_
			SNZCR.RX	(DREQEN = 0		_	0.7	_		_
		Power supplied resume detecting	to Standby SRAM and USB g unit			_	— 16	96	μA	_
		supplied to	Power-on r function dis	eset circuit low power sabled		-	12	27		—
		resume		Power-on reset circuit low power function enabled		-	5	17		—
		Increase when the RTC and		ow-speed on-chip _OCO) is in use		—	4.4	-		_
		AGT are operating	When a crystal oscillator for low clock loads is in use			-	1.0	-		_
				/stal oscillator for ock loads is in use	-	-	1.6	—		
	battery backup	while VCC is off (o function, only the		When a crystal oscillator for low		-	0.6	-		V _{BATT} = 1.8 V, VCC = 0 V
	sub-clock osci	liator operate)		clock loads is in use		-	1.2	-		V _{BATT} = 3.3 V, VCC = 0 V
				When a crystal oscillator for		-	1.1	_		V _{BATT} = 1.8 V, VCC = 0 V
				standard clock loads is in use		-	1.8	-		V _{BATT} = 3.3 V, VCC = 0 V
		on returning from	Deep	Inrush current ^{*8}	I _{RUSH}	-	160	-	mA	
	Software Stan	aby mode		Energy of inrush current ^{*8}	E _{RUSH}	-	1.0	-	μC	
Analog	During 12-bit A	VD conversion			Al _{CC}	—	0.8	1.1	mA	—
power supply	During D/A co	nversion		Without AMP output		_	0.1	0.2	mA	
current				With AMP output		_	0.6	1.1	mA	—
	Waiting for A/E	D, D/A conversion				0.5	1.0	mA		
	ADC12, DAC1	2 in standby mode	es ^{*9}			<u> -</u>	0.4	4.0	μA	—



Table 2.7Operating and standby current (2 of 2)

Parameter	Parameter					Мах	Unit	Test conditions
Reference	During 12-bit A/D conversion		AI _{REFH0}	—	70	120	μA	_
power supply	Waiting for 12-bit A/D conversion			—	0.07	0.5	μA	_
current ADC12 in standby modes (VREFH0)				—	0.07	0.5	μA	_
Reference	During D/A conversion	Without AMP output	AI _{REFH}	—	0.1	0.4	mA	_
power supply		With AMP output		—	0.1	0.4	mA	_
current (VREFH)	Waiting for D/A conversion		—	0.07	0.8	μA	—	
USB	Low speed	USB	ICCUSBLS	—	3.5	6.5	mA	VCC_USB
operating current Full speed		USB	ICCUSBFS	_	4.0	10.0	mA	VCC_USB
LDOn operating current (per unit) ^{*15}			ICCLDO	—	0.18	_	mA	_
PLL2-LDO op	perating current		I _{CCPLL2LDO}	—	0.21	—	mA	_

Note 1. Supply current values are with all output pins unloaded and all input pull-up MOSs in the off state.

Note 2. Measured with clocks supplied to the peripheral functions. This does not include the BGO operation.

Note 3. I_{CC} depends on f (ICLK) as follows.

I_{CC} Max. = 0.53 × f + 12 (max. operation in high-speed mode)

I_{CC} Typ. = 0.05 × f + 1.85 (normal operation in high-speed mode, all peripheral clocks disabled)

 I_{CC} Typ. = 0.12 × f + 0.69 (low-speed mode)

 I_{CC} Max. = 0.13 × f + 12 (sleep mode)

Note 4. This does not include the BGO operation.

Note 5. Supply of the clock signal to peripherals is stopped in this state. This does not include the BGO operation.

Note 6. FCLK, PCLKA, PCLKB, PCLKC, and PCLKD are set to divided by 64 (1.563 MHz).

Note 7. FCLK, PCLKA, PCLKB, PCLKC, and PCLKD are set to divided by 64 (3.125 MHz).

Note 8. Reference value

Note 9. When the MCU is in Software Standby mode or the MSTPCRD.MSTPD16 (12-Bit A/D Converter 0 Module Stop bit) and MSTPCRD.MSTPD20 (12-bit D/A converter module stop bit) are in the module-stop state.

Note 10. FCLK, PCLKA, PCLKB, PCLKC, and PCLKD are set to divided by 64 (15.6 kHz).

Note 11. PCLKA, PCLKB, PCLKC, and PCLKD are set to divided by 64 (512 Hz). FCLK is the same frequency as that of ICLK.

Note 12. PLL output frequency = 100MHz.

Note 13. PLL output frequency = 200MHz.

Note 14. PLL2-LDO disabled.

Note 15. n = 0, 1

Table 2.8 Coremark and normal mode current

Parameter		r Symbol Typ		Тур	Unit	Test conditions
Supply Current ^{*1}	Coremark*2 *3 *4		I _{CC}	81	µA/MHz	ICLK = 100 MHz PCLKA
	Normal modeAll peripheral clocks disabled, cache on, while (1) code 		60		= PCLKA = PCLKB = PCLKC = PCLKD = FCLK = 1.56 MHz	
		clocks disabled, cache off, while (1) code executing from		118		

Note 1. Supply current values are with all output pins unloaded and all input pull-up MOSs in the off state.

Note 2. Supply of the clock signal to peripherals is stopped in this state. This does not include the BGO operation.

Note 3. PLL output frequency = 100MHz.

Note 4. PLL2-LDO disabled.



RA4E1 Datasheet



Figure 2.2 Temperature dependency in Software Standby mode (reference data)



Figure 2.3 Temperature dependency in Deep Software Standby mode, power supplied to standby SRAM and USB resume detecting unit (reference data)





Figure 2.4 Temperature dependency in Deep Software Standby mode, power not supplied to SRAM or USB resume detecting unit, power-on reset circuit low power function disabled (reference data)





2.2.6 VCC Rise and Fall Gradient and Ripple Frequency

Table 2.9 Rise and fall gradient characteristics

Parameter			Min	Тур	Max	Unit	Test conditions
VCC rising gradient	Voltage monitor 0 reset disabled at startup	SrVCC	0.0084	—	20	ms/V	—
	Voltage monitor 0 reset enabled at startup		0.0084	_	_		—
	SCI/USB boot mode ^{*1}		0.0084	—	20		_
VCC falling gradient ^{*2}	VCC falling gradient ^{*2}			—	—	ms/V	_

Note 1. At boot mode, the reset from voltage monitor 0 is disabled regardless of the value of the OFS1.LVDAS bit.

Note 2. This applies when VBATT is used.



Table 2.10 Rising and falling gradient and ripple frequency characteristics

The ripple voltage must meet the allowable ripple frequency $f_{r (VCC)}$ within the range between the VCC upper limit (3.6 V) and lower limit (2.7 V). When the VCC change exceeds VCC ±10%, the allowable voltage change rising and falling gradient dt/dVCC must be met.

Parameter	Symbol	Min	Тур	Max	Unit	Test conditions
Allowable ripple frequency	fr (VCC)	—	—	10	kHz	Figure 2.6 V _{r (VCC)} ≤ VCC × 0.2
		_	_	1	MHz	Figure 2.6 V _{r (VCC)} ≤ VCC × 0.08
		_	—	10	MHz	Figure 2.6 V _{r (VCC)} ≤ VCC × 0.06
Allowable voltage change rising and falling gradient	dt/dVCC	1.0	_	_	ms/V	When VCC change exceeds VCC ±10%



Figure 2.6 Ripple waveform

2.2.7 Thermal Characteristics

Maximum value of junction temperature (Tj) must not exceed the value of "section 2.2.1. Tj/Ta Definition".

Tj is calculated by either of the following equations.

- $Tj = Ta + \theta ja \times Total power consumption$
- $Tj = Tt + \Psi jt \times Total power consumption$
 - Tj : Junction Temperature (°C)
 - Ta : Ambient Temperature (°C)
 - Tt : Top Center Case Temperature (°C)
 - θja : Thermal Resistance of "Junction"-to-"Ambient" (°C/W)
 - Ψjt : Thermal Resistance of "Junction"-to-"Top Center Case" (°C/W)
- Total power consumption = Voltage × (Leakage current + Dynamic current)
- Leakage current of IO = $\Sigma (I_{OL} \times V_{OL}) / Voltage + \Sigma (|I_{OH}| \times |VCC V_{OH}|) / Voltage$
- Dynamic current of IO = Σ IO (C_{in} + C_{load}) × IO switching frequency × Voltage
 - Cin: Input capacitance
 - C_{load}: Output capacitance

Regarding θ ja and Ψ jt, refer to Table 2.11.



Parameter	Package	Symbol	Value ^{*1}	Unit	Test conditions
Thermal	48-pin QFN (PWQN0048KC-A)	θја	23.9	°C/W	JESD 51-2 and 51-7
Resistance	64-pin LQFP (PLQP0064KB-C)		54.6		compliant
	48-pin QFN (PWQN0048KC-A)	Ψjt	0.28	°C/W	JESD 51-2 and 51-7
	64-pin LQFP (PLQP0064KB-C)		1.90		compliant

Table 2.11Thermal Resistance

Note 1. The values are reference values when the 4-layer board is used. Thermal resistance depends on the number of layers or size of the board. For details, refer to the JEDEC standards.

2.2.7.1 Calculation guide of I_{CC}max

Table 2.12 shows the power consumption of each unit.

Table 2.12Power consumption of each unit

Dynamic current/ Leakage current	MCU Domain	Category	Item	Frequency [MHz]	Current [uA/MHz]	Current ^{*1} [mA]
Leakage current	Analog	LDO and Leak ^{*2}	Ta = 75 °C ^{*3}	_	_	7.82
			Ta = 85 °C ^{*3}	_	_	9.13
Dynamic current	CPU	Operation with Flash and SRAM	Coremark	100	55.556	5.56
	Peripheral Unit	Timer	GPT16 (2ch) ^{*4}	100	1.788	0.18
			GPT32 (2ch) ^{*4}	100	2.115	0.21
			POEG (4 Groups)	50	1.361	0.07
			AGT (6ch) ^{*4}	50	9.228	0.46
			RTC	50	4.277	0.21
			WDT	50	0.764	0.04
			IWDT	50	0.339	0.02
		Communication interfaces	USBFS	50	9.385	0.47
			SCI (4ch) ^{*4}	100	12.477	1.25
			IIC	50	1.684	0.08
			CAN	50	1.898	0.09
			SPI	100	3.024	0.30
			QSPI	100	2.051	0.21
		Analog	ADC12	100	2.287	0.23
			DAC12	100	0.435	0.05
		Event link	ELC	50	0.865	0.04
		Security	SCE9	100	218.100	21.81
		Data processing	CRC	100	0.600	0.06
			DOC	100	0.388	0.04
		System	CAC	50	0.844	0.04
		DMA	DMAC	100	4.479	0.45
			DTC	100	4.274	0.43

Note 1. The values are guaranteed by design.

Note 2. LDO and Leak are internal voltage regulator's current and MCU's leakage current.

It is selected according to the temperature of Ta.

Note 3. Δ (Tj-Ta) = 20 °C is considered to measure the current.

Note 4. To determine the current consumption per channel, group or unit, divide Current [mA] by the number of channels, groups or units.

Table 2.13 shows the outline of operation for each unit.



Peripheral	Outline of operation
GPT	Operating modes is set to saw-wave PWM mode. GPT is operating with PCLKD.
POEG	Only clear module stop bit.
AGT	AGT is operating with PCLKB.
RTC	RTC is operating with LOCO.
WDT	WDT is operating with PCLKB.
IWDT	IWDT is operating with IWDTCLK.
USBFS	Transfer types is set to bulk transfer. USBFS is operating using Full-speed transfer (12 Mbps).
SCI	SCI is transmitting data in clock synchronous mode.
IIC	Communication format is set to I2C-bus format. IIC is transmitting data in master mode.
CAN	CAN is transmitting and receiving data in self-test mode 1.
SPI	SPI mode is set to SPI operation (4-wire method). SPI master/slave mode is set to master mode. SPI is transmitting 8-bit width data.
QSPI	QSPI is issuing Fast Read Quad I/O Instruction.
ADC12	Resolution is set to 12-bit accuracy. Data registers is set to A/D-converted value addition mode. ADC12 is converting the analog input in continuous scan mode.
DAC12	DAC12 is outputting the conversion result while updating the value of data register.
ELC	Only clear module stop bit.
SCE9	SCE9 is executing built-in self test.
CRC	CRC is generating CRC code using 32-bit CRC32-C polynomial.
DOC	DOC is operating in data addition mode.
CAC	Measurement target clocks is set to PCLKB. Measurement reference clocks is set to PCLKB. CAC is measuring the clock frequency accuracy.
DMAC	Bit length of transfer data is set to 32 bits. Transfer mode is set to block transfer mode. DMAC is transferring data from SRAM0 to SRAM0.
DTC	Bit length of transfer data is set to 32 bits. Transfer mode is set to block transfer mode. DTC is transferring data from SRAM0 to SRAM0.

Table 2.13 Outline of operation for each unit

2.2.7.2 Example of T_j calculation

Assumption :

- Package 64-pin LQFP : $\theta ja = 54.6 \text{ °C/W}$
- $Ta = 80 \circ C$
- $I_{CC}max = 40 mA$
- $VCC = 3.5 V (VCC = AVCC = VCC_USB)$
- $I_{OH} = 1 \text{ mA}, V_{OH} = VCC 0.5 \text{ V}, 12 \text{ Outputs}$
- $I_{OL} = 20 \text{ mA}, V_{OL} = 1.0 \text{ V}, 8 \text{ Outputs}$
- $I_{OL} = 1 \text{ mA}, V_{OL} = 0.5 \text{ V}, 12 \text{ Outputs}$
- $C_{in} = 8 \text{ pF}$, 16 pins, Input frequency = 10 MHz
- $C_{load} = 30 \text{ pF}$, 16 pins, Output frequency = 10 MHz



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Leakage current of IO = Σ (V_{OL} × I_{OL}) / Voltage + Σ ((VCC - V_{OH}) × I_{OH}) / Voltage = (20 mA × 1 V) × 8 / 3.5 V + (1 mA × 0.5 V) × 12 / 3.5 V + ((VCC - (VCC - 0.5 V)) × 1 mA) × 12 / 3.5 V = 45.7 mA + 1.71 mA + 1.71 mA = 49.1 mA Dynamic current of IO = Σ IO (C_{in} + C_{load}) × IO switching frequency × Voltage = ((8 pF × 16) × 10 MHz + (30 pF × 16) × 10 MHz) × 3.5 V = 21.3 mA Total power consumption = (I_{CC}max × Voltage) + (Leakage current of IO + Dynamic current of IO) × Voltage = (40 mA × 3.5 V) + (49.1 mA + 21.3 mA) × 3.5 V

= 386 mW (0.386 W)

Tj = Ta + θ ja × Total power consumption

= 80 °C + 54.6 °C/W × 0.386W

= 101.1 °C

2.3 AC Characteristics

2.3.1 Frequency

Table 2.14 Operation frequency value in high-speed mode

Parameter			Min	Тур	Мах	Unit
Operation frequency	System clock (ICLK)	f	_	—	100	MHz
	Peripheral module clock (PCLKA)		_	—	100]
	Peripheral module clock (PCLKB)		—	—	50]
	Peripheral module clock (PCLKC)		*2	—	50]
	Peripheral module clock (PCLKD)		—	—	100	
	Flash interface clock (FCLK)		*1	_	50	

Note 1. FCLK must run at a frequency of at least 4 MHz when programming or erasing the flash memory.

Note 2. When the ADC12 is used, the PCLKC frequency must be at least 1 MHz.

Table 2.15 Operation frequency value in low-speed mode

Parameter		Symbol	Min	Тур	Мах	Unit
Operation frequency	System clock (ICLK)	f	—	—	1	MHz
	Peripheral module clock (PCLKA)		—	—	1	
	Peripheral module clock (PCLKB)		—	—	1	
	Peripheral module clock (PCLKC) *2		*2	—	1	
	Peripheral module clock (PCLKD)		—	—	1	
	Flash interface clock (FCLK) ^{*1}		_	—	1	

Note 1. Programming or erasing the flash memory is disabled in low-speed mode.

Note 2. When the ADC12 is used, the PCLKC frequency must be set to at least 1 MHz.



Parameter		Symbol	Min	Тур	Мах	Unit
Operation frequency	System clock (ICLK)	f	29.4	—	36.1	kHz
	Peripheral module clock (PCLKA)		—	—	36.1	
	Peripheral module clock (PCLKB)		—	—	36.1	
	Peripheral module clock (PCLKC) *2		—	_	36.1	
	Peripheral module clock (PCLKD)		—	—	36.1	
	Flash interface clock (FCLK) ^{*1}		29.4	—	36.1	

Table 2.16 Operation frequency value in Subosc-speed mode

Note 1. Programming or erasing the flash memory is disabled in Subosc-speed mode. Note 2. The ADC12 cannot be used.

2.3.2 **Clock Timing**

Table 2.17 Clock timing except for sub-clock oscillator (1 of 2)

Parameter		Symbol	Min	Тур	Мах	Unit	Test conditions	
EXTAL external clock input cycle tin	ne	t _{EXcyc}	41.66	—	_	ns	Figure 2.7	
EXTAL external clock input high pul	se width	t _{EXH}	15.83	—	_	ns	•	
EXTAL external clock input low puls	se width	t _{EXL}	15.83	-	_	ns		
XTAL external clock rise time		t _{EXr}	—	-	5.0	ns		
EXTAL external clock fall time		t _{EXf}	—	-	5.0	ns		
Main clock oscillator frequency	ain clock oscillator frequency		8	-	24	MHz	—	
Main clock oscillation stabilization w	vait time (crystal) ^{*1}	t _{MAINOSCWT}	_	—	*1	ms	Figure 2.8	
LOCO clock oscillation frequency		f _{LOCO}	29.4912	32.768	36.0448	kHz	_	
LOCO clock oscillation stabilization	wait time	t _{LOCOWT}	_	—	60.4	μs	Figure 2.9	
ILOCO clock oscillation frequency		f _{ILOCO}	13.5	15	16.5	kHz	_	
MOCO clock oscillation frequency		f _{MOCO}	6.8	8	9.2	MHz	_	
MOCO clock oscillation stabilization	n wait time	t _{мосоwт}	_	—	15.0	μs	—	
HOCO clock oscillator oscillation	Without FLL	f _{HOCO16}	15.78	16	16.22	MHz	–20 ≤ Ta ≤ 85°C	
frequency		f _{HOCO18}	17.75	18	18.25			
		f _{HOCO20}	19.72	20	20.28			
		f _{HOCO16}	15.71	16	16.29		–40 ≤ Ta ≤ –20°C	
		f _{HOCO18}	17.68	18	18.32			
		f _{HOCO20}	19.64	20	20.36			
	With FLL	f _{HOCO16}	15.960	16	16.040		–40 ≤ Ta ≤ 85°C	
		f _{HOCO18}	17.955	18	18.045		Sub-clock frequency accuracy is ±50 ppm.	
		f _{HOCO20}	19.950	20	20.050			
HOCO clock oscillation stabilization	wait time ^{*2}	t _{носоwт}	—	—	64.7	μs	—	
HOCO period jitter		_	—	±85		ps	—	
FLL stabilization wait time		t _{FLLWT}	—	—	1.8	ms	_	
PLL clock frequency		f _{PLL}	100		200	MHz	_	
PLL2 clock frequency		f _{PLL2}	120	_	240	MHz		
PLL/PLL2 clock oscillation stabilizat	tion wait time	t _{PLLWT}	_	_	174.9	μs	Figure 2.10	
				-	-			



Parameter		Symbol	Min	Тур	Max	Unit	Test conditions
PLL/PLL2 period jitter	f _{PLL} , f _{PLL2} ≥ 120MHz	—	—	±100	—	ps	_
	f _{PLL} , f _{PLL2} < 120MHz	—	—	±120	_	ps	_
PLL/PLL2 long term jitter		_	—	±300	_	ps	Term: 1µs, 10µs

Table 2.17 Clock timing except for sub-clock oscillator (2 of 2)

Note 1. When setting up the main clock oscillator, ask the oscillator manufacturer for an oscillation evaluation, and use the results as the recommended oscillation stabilization time. Set the MOSCWTCR register to a value equal to or greater than the recommended value.

After changing the setting in the MOSCCR.MOSTP bit to start main clock operation, read the OSCSF.MOSCSF flag to confirm that it is 1, and then start using the main clock oscillator.

Note 2. This is the time from release from reset state until the HOCO oscillation frequency (f_{HOCO}) reaches the range for guaranteed operation.

Table 2.18 Clock timing for the sub-clock oscillator

Parameter	Symbol	Min	Тур	Max	Unit	Test conditions
Sub-clock frequency	f _{SUB}	—	32.768	—	kHz	-
Sub-clock oscillation stabilization wait time	t _{SUBOSCWT}	—	_	*1	s	Figure 2.11

Note 1. When setting up the sub-clock oscillator, ask the oscillator manufacturer for an oscillation evaluation and use the results as the recommended oscillation stabilization time.

After changing the setting in the SOSCCR.SOSTP bit to start sub-clock operation, only start using the sub-clock oscillator after the sub-clock oscillation stabilization time elapses with an adequate margin. A value that is two times the value shown is recommended.



Figure 2.7 EXTAL external clock input timing













Figure 2.10 PLL/PLL2 clock oscillation start timing



Figure 2.11 Sub-clock oscillation start timing

2.3.3 Reset Timing

Table 2.19Reset timing (1 of 2)

Parameter			Min	Тур	Max	Unit	Test conditions
RES pulse width	Power-on	t _{RESWP}	0.7	—	—	ms	Figure 2.12
	Deep Software Standby mode	t _{RESWD}	0.6	—	—	ms	Figure 2.13
	Software Standby mode, Subosc-speed mode	t _{RESWS}	0.3	_	—	ms	
	All other	t _{RESW}	200	—	—	μs	
Wait time after RES cancellation		t _{RESWT}	-	37.3	41.2	μs	Figure 2.12



Table 2.19 Reset timing (2 of 2)

Parameter	Symbol	Min	Тур	Мах	Unit	Test conditions
Wait time after internal reset cancellation (IWDT reset, WDT reset, software reset, SRAM parity error reset, bus master MPU error reset, TrustZone error reset)	t _{RESW2}		324	397.7	μs	—







Figure 2.13 Reset input timing

2.3.4 Wakeup Timing

Table 2.20Timing of recovery from low power modes (1 of 2)

Parameter			Symbol	Min	Тур	Max	Unit	Test conditions
Recovery time from Software Standby	Crystal resonator connected to main clock oscillator	System clock source is main clock oscillator ^{*2}	t _{SBYMC} *13	—	2.1	2.4	ms	Figure 2.14 The division ratio of all oscillators is 1.
mode ^{*1}	OSCIIIALOI	System clock source is PLL with main clock oscillator ^{*3}	t_{SBYPC}^{*13} — 2.2 2.6 ms					
	External clock input to main clock oscillator	System clock source is main clock oscillator ^{*4}	t _{SBYEX} *13	—	45	125	μs	
		System clock source is PLL with main clock oscillator ^{*5}	t _{SBYPE} *13		170	255	μs	
	System clock source is su	b-clock oscillator ^{*6 *11}	t _{SBYSC} *13	—	0.7	0.8	ms	
	System clock source is LC	DCO ^{*7 *11}	t _{SBYLO} *13	—	0.7	0.9	ms	
	System clock source is H	OCO clock oscillator ^{*8}	t _{SBYHO} *13	—	55	130	μs	
	System clock source is Pl	L with HOCO ^{*9}	t _{SBYPH} *13	—	175	265	μs	
	System clock source is M	OCO clock oscillator ^{*10}	t _{SBYMO} *13	_	35	65	μs	



Parameter		Symbol	Min	Тур	Мах	Unit	Test conditions
Recovery time from Deep Software	DPSBYCR.DEEPCUT[1] = 0 and DPSWCR.WTSTS[5:0] = 0x0E	t _{DSBY}	-	0.38	0.54	ms	Figure 2.15
Standby mode	DPSBYCR.DEEPCUT[1] = 1 and DPSWCR.WTSTS[5:0] = 0x19	t _{DSBY}	—	0.55	0.73	ms	
Wait time after cancel	ation of Deep Software Standby mode	t _{DSBYWT}	56		57	t _{cyc}	
Recovery time from Software Standby	High-speed mode when system clock source is HOCO (20 MHz)	t _{SNZ}	-	35 ^{*12}	70 ^{*12}	μs	Figure 2.16
mode to Snooze mode	High-speed mode when system clock source is MOCO (8 MHz)	t _{SNZ}	-	11 ^{*12}	14 ^{*12}	μs	

Note 1. The recovery time is determined by the system clock source. When multiple oscillators are active, the recovery time can be determined with the following equation:

Total recovery time = recovery time for an oscillator as the system clock source + the longest tSBYOSCWT in the active oscillators - tSBYOSCWT for the system clock + 2 LOCO cycles (when LOCO is operating) + Subosc is oscillating and MSTPC0 = 0 (CAC module stop)

Note 2. When the frequency of the crystal is 24 MHz (Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 0x05) and the greatest value of the internal clock division setting is 1.

Note 3. When the frequency of PLL is 200 MHz (Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 0x05) and the greatest value of the internal clock division setting is 4.

Note 4. When the frequency of the external clock is 24 MHz (Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 0x00) and the greatest value of the internal clock division setting is 1.

Note 5. When the frequency of PLL is 200 MHz (Main Clock Oscillator Wait Control Register (MOSCWTCR) is set to 0x00) and the greatest value of the internal clock division setting is 4.

Note 6. The Sub-clock oscillator frequency is 32.768 kHz and the greatest value of the internal clock division setting is 1.

Note 7. The LOCO frequency is 32.768 kHz and the greatest value of the internal clock division setting is 1.

Note 8. The HOCO frequency is 20 MHz and the greatest value of the internal clock division setting is 1.

Note 9. The PLL frequency is 200 MHz and the greatest value of the internal clock division setting is 4.

Note 10. The MOCO frequency is 8 MHz and the greatest value of the internal clock division setting is 1.

Note 11. In Subosc-speed mode, the sub-clock oscillator or LOCO continues oscillating in Software Standby mode.

Note 12. When the SNZCR.RXDREQEN bit is set to 0, the following time is added as the power supply recovery time: 16 µs (typical), 48 µs (maximum).

Note 13. The recovery time can be calculated with the equation of tSBYOSCWT + tSBYSEQ. And they can be determined with the following value and equation. For n, the greatest value is selected from among the internal clock division settings.

Wakeup time	ТҮР		MAX			
	tSBYOSCWT	tSBYSEQ	tSBYOSCWT	tSBYSEQ		
tSBYMC	(MSTS[7:0]*32 + 3) / 0.262	35 + 18 / flCLK + 4n / fMAIN	(MSTS[7:0]*32 + 14 / 0.236	62 + 18 / fICLK + 4n / fMAIN	μs	
tSBYPC	(MSTS[7:0]*32 + 34) / 0.262	35 + 18 / fICLK + 4n / fPLL	(MSTS[7:0]*32 + 45) / 0.236	62 + 18 / flCLK + 4n / fPLL	μs	
tSBYEX	10	35 + 18 / fICLK + 4n / fEXMAIN	62	62 + 18 / fICLK + 4n / fEXMAIN	μs	
tSBYPE	135	35 + 18 / flCLK + 4n / fPLL	192	62 + 18 / flCLK + 4n / fPLL	μs	
tSBYSC	0	35 + 18 / fICLK + 4n / fSUB	0	62 + 18 / flCLK + 4n / fSUB	μs	
tSBYLO	0	35 + 18 / flCLK + 4n / fLOCO	0	62 + 18 / flCLK + 4n / fLOCO	μs	
tSBYHO	20	35 + 18 / fICLK + 4n / fHOCO	67	62 + 18 / flCLK + 4n / fHOCO	μs	
tSBYPH	140	35 + 18 / flCLK + 4n / fPLL	202	62 + 18 / flCLK + 4n / fPLL	μs	
tSBYMO	0	35 + 18 / fICLK + 4n / fMOCO	0	62 + 18 / flCLK + 4n / fMOCO	μs	





Figure 2.14 Software Standby mode cancellation timing



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Figure 2.15 Deep Software Standby mode cancellation timing



Figure 2.16 Recovery timing from Software Standby mode to Snooze mode

2.3.5 NMI and IRQ Noise Filter

Table 2.21 NMI and IRQ noise filter

Parameter	Symbol	Min	Тур	Max	Unit	Test conditions		
NMI pulse	t _{NMIW}	200	—	—	ns	NMI digital filter	t _{Pcyc} × 2 ≤ 200 ns	
width		t _{Pcyc} × 2 ^{*1}	_	—		disabled	t _{Pcyc} × 2 > 200 ns	
		200	_	—		NMI digital filter	t _{NMICK} × 3 ≤ 200 ns	
		$t_{NMICK} \times 3.5^{*2}$	—	—		enabled	t _{NMICK} × 3 > 200 ns	
IRQ pulse	t _{IRQW}	200	_	—	ns	IRQ digital filter	t _{Pcyc} × 2 ≤ 200 ns	
width		t _{Pcyc} × 2 ^{*1}	—	—		disabled	t _{Pcyc} × 2 > 200 ns	
		200	_	—		IRQ digital filter	t _{IRQCK} × 3 ≤ 200 ns	
		t _{IRQCK} × 3.5 ^{*3}	—	_		enabled	t _{IRQCK} × 3 > 200 ns	



Note: 200 ns minimum in Software Standby mode.

- If the clock source is switched, add 4 clock cycles of the switched source. Note:
- Note 1. t_{Pcvc} indicates the PCLKB cycle.
- Note 2. t_{NMICK} indicates the cycle of the NMI digital filter sampling clock.
- Note 3. t_{IRQCK} indicates the cycle of the IRQi digital filter sampling clock.







Figure 2.18 **IRQ** interrupt input timing

2.3.6 I/O Ports, POEG, GPT, AGT, and ADC12 Trigger Timing

I/O ports, POEG, GPT, AGT, and ADC12 trigger timing Table 2.22

GPT32 Conditions:

High drive output is selected in the Port Drive Capability bit in the PmnPFS register. AGT Conditions:

Middle drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter			Symbol	Min	Max	Unit	Test conditions
I/O ports	Input data pulse width		t _{PRW}	1.5	—	t _{Pcyc}	Figure 2.19
POEG	POEG input trigger pulse width		t _{POEW}	3	—	t _{Pcyc}	Figure 2.20
GPT	Input capture pulse width	Single edge	t _{GTICW}	1.5	—	t _{PDcyc}	Figure 2.21
		Dual edge		2.5	—		
	GTIOCxY output skew (x = 1, 2, Y = A or B)	Middle drive buffer	t _{GTISK} *1	—	4	ns	Figure 2.22
		High drive buffer		_	4		
	GTIOCxY output skew (x = 4, 5, Y = A or B)	Middle drive buffer		_	4		
		High drive buffer		_	4		
	GTIOCxY output skew (x = 1, 2, 4, 5, Y = A or B)	Middle drive buffer		_	6		
		High drive buffer		_	6		
AGT	AGTIO, AGTEE input cycle		t _{ACYC} *2	100	—	ns	Figure 2.23
	AGTIO, AGTEE input high width, low width		t _{ACKWH} , t _{ACKWL}	40	_	ns	
	AGTIO, AGTO, AGTOA, AGTOB output cycle		t _{ACYC2}	62.5	—	ns	
ADC12	ADC12 trigger input pulse width		t _{TRGW}	1.5	—	t _{Pcyc}	Figure 2.24

tPcvc: PCLKB cycle, tPDcvc: PCLKD cycle. Note:

Note 1. This skew applies when the same driver I/O is used. If the I/O of the middle and high drivers is mixed, operation is not guaranteed.

Constraints on input cycle: Note 2.

When not switching the source clock: $t_{Pcyc} \times 2 < t_{ACYC}$ should be satisfied.

When switching the source clock: $t_{Pcyc} \times 6 < t_{ACYC}$ should be satisfied.
















Figure 2.22 GPT output delay skew









Figure 2.24 ADC12 trigger input timing

2.3.7 CAC Timing

Table 2.23 CAC timing

Parameter			Symbol	Min	Тур	Max	Unit	Test conditions
CAC	CACREF input pulse width	t _{PBcyc} ≤ t _{cac} *1	t _{CACREF}	$4.5 \times t_{cac} + 3 \times t_{PBcyc}$	—	—	ns	_
	WIGHT	t _{PBcyc} > t _{cac} *1		$5 \times t_{cac} + 6.5 \times t_{PBcyc}$	—	—	ns	

Note: t_{PBcyc}: PCLKB cycle.

Note 1. t_{cac} : CAC count clock source cycle.



2.3.8 SCI Timing

Table 2.24 SCI timing (1)

Conditions: High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

ra	meter		Symbol	Min	Max	Unit	Test conditions	
1	Input clock cycle	Asynchronous	t _{Scyc}	4	—	t _{Pcyc}	Figure 2.25	
		Clock synchronous]	6	_	1		
	Input clock pulse width		t _{SCKW}	0.4	0.6	t _{Scyc}		
┝	nput clock rise time			—	5	ns		
	Input clock fall time		t _{SCKf}	—	5	ns	-	
	Output clock cycle	Asynchronous	t _{Scyc}	6 (other than SCI1, SCI2) 8 (SCI1, SCI2)	-	t _{Pcyc}		
		Clock synchronous	1	4	_			
	Output clock pulse width		t _{SCKW}	0.4	0.6	t _{Scyc}		
ſ	Output clock rise time			—	5	ns		
	Output clock fall time			—	5	ns	-	
	Transmit data delay	Clock synchronous master mode (internal clock)	t _{TXD}	—	5	ns	Figure 2.26	
		Clock synchronous slave mode (external clock)	t _{TXD}	_	25	ns		
	Receive data setup time	Clock synchronous master mode (internal clock)	t _{RXS}	15	-	ns		
		Clock synchronous slave mode (external clock)	t _{RXS}	5	-	ns		
ľ	Receive data hold time	Clock synchronous	t _{RXH}	5	_	ns	1	

Note: t_{Pcyc}: PCLKA cycle.







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Figure 2.26 SCI input/output timing in clock synchronous mode

Table 2.25 SCI timing (2)

Conditions: High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter			Symbol	Min	Мах	Unit	Test conditions
Simple SPI	SCK clock cycle output (mast	er)	t _{SPcyc}	4	65536	t _{Pcyc}	Figure 2.27
	SCK clock cycle input (slave)	SCK clock cycle input (slave)			65536	1	
	SCK clock high pulse width	t _{SPCKWH}	0.4	0.6	t _{SPcyc}		
	SCK clock low pulse width		t _{SPCKWL}	0.4	0.6	t _{SPcyc}	
	SCK clock rise and fall time		t _{SPCKr} , t _{SPCKf}	-	5	ns	
	Data input setup time	master	t _{SU}	15	—	ns	Figure 2.28 to Figure
		slave		5	_	ns	2.31
	Data input hold time		t _H	5	_	ns	
	SS input setup time		t _{LEAD}	1	_	t _{SPcyc}	
	SS input hold time		t _{LAG}	1	—	t _{SPcyc}	
	Data output delay	master	t _{OD}	-	5	ns	
		slave		—	25	ns	
	Data output hold time	Data output hold time		-5	_	ns	
	Data rise and fall time		t _{Dr} , t _{Df}	-	5	ns	
	SS input rise and fall time		t _{SSLr} , t _{SSLf}	-	5	ns	
	Slave access time		t _{SA}	-	3 × t _{Pcyc} + 25	ns	Figure 2.31
	Slave output release time		t _{REL}	—	3 × t _{Pcyc} + 25	ns	

Note: t_{Pcyc}: PCLKA cycle.









SCI simple SPI mode timing for master when CKPH = 1 Figure 2.28



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Figure 2.29 SCI simple SPI mode timing for master when CKPH = 0



Figure 2.30 SCI simple SPI mode timing for slave when CKPH = 1





Figure 2.31 SCI simple SPI mode timing for slave when CKPH = 0

Table 2.26SCI timing (3)

Conditions: Middle drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Parameter		Symbol	Min	Max	Unit	Test conditions	
Simple IIC	SDA input rise time	t _{Sr}	—	1000	ns	Figure 2.32	
(Standard mode)	SDA input fall time	t _{Sf}	—	300	ns		
	SDA input spike pulse removal time	t _{SP}	0	4 × t _{IICcyc}	ns	-	
	Data input setup time	t _{SDAS}	250	_	ns	-	
	Data input hold time	t _{SDAH}	0	_	ns	-	
	SCL, SDA capacitive load	C _b ^{*1}	_	400	pF		
Simple IIC	SDA input rise time	t _{Sr}	—	300	ns	Figure 2.32	
(Fast mode)	SDA input fall time	t _{Sf}	_	300	ns	-	
	SDA input spike pulse removal time	t _{SP}	0	4 × t _{IICcyc}	ns	-	
	Data input setup time	t _{SDAS}	100	_	ns	-	
	Data input hold time	t _{SDAH}	0	_	ns		
	SCL, SDA capacitive load	C _b ^{*1}	_	400	pF		

Note: t_{IICcyc} : IIC internal reference clock (IIC ϕ) cycle.

Note 1. C_b indicates the total capacity of the bus line.



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Figure 2.32 SCI simple IIC mode timing



2.3.9 SPI Timing

Table 2.27 SPI timing

Conditions: High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

am	neter		Symbol	Min	Мах	Unit	Test conditions	
	RSPCK clock cycle	Master	t _{SPcyc}	2	4096	t _{Pcyc}	Figure 2.33	
		Slave		4	4096]		
	RSPCK clock high pulse width	Master	tspcкwн	$(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3$	_	ns		
		Slave		0.4	0.6	t _{SPcyc}		
	RSPCK clock low pulse width	Master	t _{SPCKWL}	$(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3$	_	ns		
		Slave		0.4 0.6				
	RSPCK clock rise and	Master	t _{SPCKr} , t _{SPCKf}	-	5	ns	-	
	fall time	Slave	-	—	1	μs	-	
	Data input setup time	Master	t _{SU}	4	_	ns	Figure 2.34 to Figu	
		Slave	-	5	_		2.39	
	Data input hold time	Master (PCLKA division ratio set to 1/2)	t _{HF}	0	_	ns	-	
	(PC divi set othe	Master (PCLKA division ratio set to a value other than 1/2)	t _H	t _{Pcyc}	_	-		
		Slave	t _H	20	—]		
	SSL setup time	e Master t _l	t _{LEAD}	$N \times t_{SPcyc} - 10^{*1}$	N × t _{SPcyc} + 100 ^{*1}	ns		
		Slave		4 × t _{Pcyc}	—	ns		
	SSL hold time	Master	t _{LAG}	N × t _{SPcyc} - 10 ^{*2}	N × t _{SPcyc} + 100 ^{*2}	ns	-	
		Slave	-	4 × t _{Pcyc}	_	ns		
	Data output delay	Master	t _{OD1}	—	6.3	ns	-	
			t _{OD2}	_	6.3	-		
		Slave	t _{OD}		20	-		
	Data output hold time	Master	t _{OH}	0	_	ns	-	
		Slave		0	_	-		
	Successive transmission delay	Master	t _{TD}	t _{SPcyc} + 2 × t _{Pcyc}	8 × t _{SPcyc} + 2 × t _{Pcyc}	ns	-	
		Slave	-	4 × t _{Pcyc}				
	MOSI and MISO rise	Output	t _{Dr} , t _{Df}		5	ns	1	
	and fall time	Input	1	_	1	μs	1	
	SSL rise and fall time	Output	t _{SSLr} , t _{SSLf}		5	ns	_	
		Input		_	1	μs	1	
	Slave access time		t _{SA}		25	ns	Figure 2.38 and	
-	Slave output release tin				25	-	Figure 2.39	

Note: t_{Pcyc}: PCLKA cycle.



- Note: Must use pins that have a letter appended to their name, for instance "_A", "_B", to indicate group membership. For the SPI interface, the AC portion of the electrical characteristics is measured for each group.
- Note 1. N is set to an integer from 1 to 8 by the SPCKD register.
- Note 2. N is set to an integer from 1 to 8 by the SSLND register.









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Figure 2.37 SPI timing for master when CPHA = 1 and the bit rate is set to PCLKA/2











2.3.10 QSPI Timing

Table 2.28 QSPI timing

Conditions: High drive output is selected in the Port Drive Capability bit in the PmnPFS register.

Paramete	er	Symbol	Min	Мах	Unit	Test conditions
QSPI	QSPCK clock cycle	t _{QScyc}	2	48	t _{Pcyc}	Figure 2.40
	QSPCK clock high pulse width	t _{QSWH}	t _{QScyc} × 0.4	-	ns	
	QSPCK clock low pulse width	t _{QSWL}	t _{QScyc} × 0.4	-	ns	
	Data input setup time	t _{Su}	10	—	ns	Figure 2.41
	Data input hold time	t _{IH}	0	—	ns	
	QSSL setup time	t _{LEAD}	$(N + 0.5) \times t_{Qscyc} - 5^{*1}$	(N + 0.5) × t _{Qscyc} + 100 ^{*1}	ns	
	QSSL hold time	t _{LAG}	$(N + 0.5) \times t_{Qscyc} - 5^{*2}$	(N + 0.5) × t _{Qscyc} + 100 ^{*2}	ns	
	Data output delay	t _{OD}	—	4	ns	
	Data output hold time	t _{OH}	-3.3	_	ns	
	Successive transmission delay	t _{TD}	1	16	t _{QScyc}	

Note: t_{Pcyc}: PCLKA cycle.

Note 1. N is set to 0 or 1 in SFMSLD.

Note 2. N is set to 0 or 1 in SFMSHD.







Figure 2.40 QSPI clock timing



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IIC Timing 2.3.11

Table 2.29 IIC timing (1) (1 of 2)

(1) Conditions: Middle drive output is selected in the Port Drive Capability bit in the PmnPFS register for the following pins: SDA0_B, SCL0_B. (2) The following pins do not require setting: SCL0_A, SDA0_A.

(3) Use pins that have a letter appended to their names, for instance "_A" or "_B", to indicate group membership. For the IIC interface, the AC portion of the electrical characteristics is measured for each group.

Parameter		Symbol	Min	Max	Unit	Test conditions
IIC (Step dand reads	SCL input cycle time	t _{SCL}	6 (12) × t _{IICcyc} + 1300	_	ns	Figure 2.42
(Standard mode, SMBus)	SCL input high pulse width	t _{SCLH}	3 (6) × t _{IICcyc} + 300	-	ns	-
ICFER.FMPE = 0	SCL input low pulse width	t _{SCLL}	3 (6) × t _{IICcyc} + 300	_	ns	-
	SCL, SDA rise time	t _{Sr}	—	1000	ns	-
	SCL, SDA fall time	t _{Sf}	—	300	ns	-
	SCL, SDA input spike pulse removal time	t _{SP}	0	1 (4) × t _{IICcyc}	ns	
	SDA input bus free time when wakeup function is disabled	t _{BUF}	3 (6) × t _{IICcyc} + 300	_	ns	
	SDA input bus free time when wakeup function is enabled	t _{BUF}	$3 (6) \times t_{IICcyc} + 4 \times t_{Pcyc} + 300$	_	ns	
	START condition input hold time when wakeup function is disabled	t _{STAH}	t _{IICcyc} + 300	_	ns	
	START condition input hold time when wakeup function is enabled	t _{STAH}	1 (5) × t_{IICcyc} + t_{Pcyc} + 300	_	ns	
	Repeated START condition input setup time	t _{STAS}	1000	_	ns	
	STOP condition input setup time	t _{STOS}	1000	-	ns	-
	Data input setup time	t _{SDAS}	t _{IICcyc} + 50	-	ns	
	Data input hold time	t _{SDAH}	0	-	ns	
	SCL, SDA capacitive load	C _b *2	-	400	pF	



Table 2.29 IIC timing (1) (2 of 2)

(1) Conditions: Middle drive output is selected in the Port Drive Capability bit in the PmnPFS register for the following pins: SDA0_B, SCL0_B.

(2) The following pins do not require setting: SCL0_A, SDA0_A.

(3) Use pins that have a letter appended to their names, for instance "_A" or "_B", to indicate group membership. For the IIC interface, the AC portion of the electrical characteristics is measured for each group.

Parameter		Symbol	Min	Max	Unit	Test conditions
IIC (Feature da)	SCL input cycle time	t _{SCL}	6 (12) × t _{IICcyc} + 600	_	ns	Figure 2.42
(Fast mode)	SCL input high pulse width	t _{SCLH}	3 (6) × t _{IICcyc} + 300	_	ns	-
	SCL input low pulse width	t _{SCLL}	3 (6) × t _{IICcyc} + 300	_	ns	
	SCL, SDA rise time	t _{Sr}	20 × (external pullup voltage/5.5V) ^{*1}	300	ns	-
	SCL, SDA fall time	t _{Sf}	20 × (external pullup voltage/5.5V) ^{*1}	300	ns	-
	SCL, SDA input spike pulse removal time	t _{SP}	0	1 (4) × t _{IICcyc}	ns	
	SDA input bus free time when wakeup function is disabled	t _{BUF}	3 (6) × t _{IICcyc} + 300	—	ns	
	SDA input bus free time when wakeup function is enabled	t _{BUF}	$\begin{array}{c} 3 \ (6) \times t_{\rm IICcyc} + 4 \times t_{\rm Pcyc} + \\ 300 \end{array}$	_	ns	
	START condition input hold time when wakeup function is disabled	t _{STAH}	t _{IICcyc} + 300	-	ns	-
	START condition input hold time when wakeup function is enabled	t _{STAH}	1 (5) × t_{IICcyc} + t_{Pcyc} + 300	_	ns	
	Repeated START condition input setup time	t _{STAS}	300	-	ns	-
	STOP condition input setup time	t _{STOS}	300	_	ns	-
	Data input setup time	t _{SDAS}	t _{IICcyc} + 50	_	ns	1
	Data input hold time	t _{SDAH}	0	_	ns	1
	SCL, SDA capacitive load	C _b *2	-	400	pF	1

Note: t_{IICcyc} : IIC internal reference clock (IIC ϕ) cycle, t_{Pcyc} : PCLKB cycle.

Note: Values in parentheses apply when ICMR3.NF[1:0] is set to 11b while the digital filter is enabled with ICFER.NFE set to 1. Note: Must use pins that have a letter appended to their name, for instance "_A", "_B", to indicate group membership. For the IIC interface, the AC portion of the electrical characteristics is measured for each group.

Note 1. Only supported for SCL0_A and SDA0_A.

Note 2. Cb indicates the total capacity of the bus line.



Table 2.30 IIC timing (2)

Setting of the SCL0_A, SDA0_A pins is not required with the Port Drive Capability bit in the PmnPFS register.

Parameter		Symbol	Min	Max Ur		nit Test conditions		
IIC (Fast-mode+)	SCL input cycle time	t _{SCL}	6 (12) × t _{IICcyc} + 240	—	ns	Figure 2.42		
ICFER.FMPE = 1	SCL input high pulse width	t _{SCLH}	3 (6) × t _{IICcyc} + 120	—	ns			
	SCL input low pulse width	t _{SCLL}	3 (6) × t _{IICcyc} + 120	—	ns			
	SCL, SDA rise time	t _{Sr}	—	120	ns			
	SCL, SDA fall time	t _{Sf}	20 × (external pullup voltage/ 5.5V)	120	ns			
	SCL, SDA input spike pulse removal time	t _{SP}	0	1 (4) × tIICcyc	ns			
	SDA input bus free time when wakeup function is disabled	t _{BUF}	3 (6) × t _{IICcyc} + 120	—	ns			
	SDA input bus free time when wakeup function is enabled	t _{BUF}	3 (6) × t _{IICcyc} + 4 × t _{Pcyc} + 120	— ns		-		
	Start condition input hold time when wakeup function is disabled	t _{STAH}	t _{IICcyc} + 120	—	ns	1		
	START condition input hold time when wakeup function is enabled	t _{STAH}	1 (5) × t _{IICcyc} + t _{Pcyc} + 120	—	ns			
	Restart condition input setup time	t _{STAS}	120	—	ns			
	Stop condition input setup time	t _{STOS}	120	—	ns			
	Data input setup time	t _{SDAS}	t _{IICcyc} + 30	—	ns			
	Data input hold time	t _{SDAH}	0	—	ns	1		
	SCL, SDA capacitive load	C _b *1	—	550	pF			

 Note:
 t_{IICcyc}: IIC internal reference clock (IICφ) cycle, t_{Pcyc}: PCLKB cycle.

 Note:
 Values in parentheses apply when ICMR3.NF[1:0] is set to 11b while the digital filter is enabled with ICFER.NFE set to 1.

 Note 1.
 Cb indicates the total capacity of the bus line.



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2.4 USB Characteristics

2.4.1 USBFS Timing

Table 2.31 USBFS low-speed characteristics for host only (USB_DP and USB_DM pin characteristics) Out times 1/00 1/00 1/00 1/00 1/00

Parameter		Symbol	Min	Тур	Max	Unit	Test conditions
Input	Input high voltage	V _{IH}	2.0	_	—	V	—
characteristics	Input low voltage	VIL	—	—	0.8	V	—
	Differential input sensitivity	V _{DI}	0.2	—	—	V	USB_DP - USB_DM
	Differential common-mode range	V _{CM}	0.8	—	2.5	V	—
Output	Output high voltage	V _{OH}	2.8	—	3.6	V	I _{OH} = –200 μA
characteristics	Output low voltage	V _{OL}	0.0	—	0.3	V	I _{OL} = 2 mA
	Cross-over voltage	V _{CRS}	1.3	—	2.0	V	Figure 2.43
	Rise time	t _{LR}	75	—	300	ns	
	Fall time	t _{LF}	75	—	300	ns	
	Rise/fall time ratio	t _{LR} / t _{LF}	80	—	125	%	t _{LR} / t _{LF}
Pull-up and pull-down characteristics	USB_DP and USB_DM pull-down resistance in host controller mode	R _{pd}	14.25	—	24.80	kΩ	_











Table 2.32 USBFS full-speed characteristics (USB_DP and USB_DM pin characteristics)

Conditions: VCC = AVCC0 = VCC_USB = VBATT = 3.0 to 3.6 V, 2.7 ≤ VREFH0/VREFH ≤ AVCC0, USBCLK = 48 MHz

Parameter		Symbol	Min	Тур	Max	Unit	Test conditions
Input	Input high voltage	V _{IH}	2.0	—	—	V	—
characteristics	Input low voltage	V _{IL}	—	—	0.8	V	—
	Differential input sensitivity	V _{DI}	0.2	—	—	V	USB_DP - USB_DM
	Differential common-mode range	V _{CM}	0.8	—	2.5	V	—
Output	Output high voltage	V _{OH}	2.8	—	3.6	V	I _{OH} = –200 μA
characteristics	Output low voltage	V _{OL}	0.0	—	0.3	V	I _{OL} = 2 mA
	Cross-over voltage	V _{CRS}	1.3	—	2.0	V	Figure 2.45
	Rise time	t _{LR}	4	—	20	ns	
	Fall time	t _{LF}	4	—	20	ns	
	Rise/fall time ratio	t _{LR} / t _{LF}	90	_	111.11	%	t _{FR} / t _{FF}
	Output resistance	Z _{DRV}	28	_	44	Ω	USBFS: Rs = 27 Ω included
Pull-up and	DM pull-up resistance in device controller	R _{pu}	0.900	_	1.575	kΩ	During idle state
pull-down characteristics	mode		1.425	-	3.090	kΩ	During transmission and reception
	USB_DP and USB_DM pull-down resistance in host controller mode	R _{pd}	14.25	-	24.80	kΩ	_









Figure 2.46 Test circuit in full-speed mode

Table 2.33 USBFS characteristics (USB_DP and USB_DM pin characteristics)

Conditions: VCC = AVCC0 = VCC_USB = VBATT = 3.0 to 3.6 V, 2.7 ≤ VREFH0/VREFH ≤ AVCC0, USBCLK = 48 MHz

Parameter	Parameter		Min	Тур	Max	Unit	Test conditions
Battery Charging	D+ sink current	I _{DP_SINK}	25	-	175	μA	_
Specification	D- sink current	I _{DM_SINK}	25	_	175	μA	—
	DCD source current	I _{DP_SRC}	7	_	13	μA	—
	Data detection voltage	V _{DAT_REF}	0.25	_	0.4	V	_
	D+ source voltage	V _{DP_SRC}	0.5	_	0.7	V	Output current = 250 µA
	D- source voltage	V _{DM_SRC}	0.5	—	0.7	V	Output current = 250 µA

2.5 ADC12 Characteristics

Table 2.34 A/D conversion characteristics for unit 0 (1 of 2)

Parameter	Min	Тур	Мах	Unit	Test conditions
Frequency	1	—	50	MHz	_
Analog input capacitance	—	—	30	pF	—
Quantization error	_	±0.5	—	LSB	—
Resolution	—	—	12	Bits	_



Table 2.34 A/D conversion characteristics for unit 0 (2 of 2)

Conditions: PCLKC = 1 to 50 MHz

Parameter			Min	Тур	Max	Unit	Test conditions
High-precision high-speed channels (AN000 to AN002)	Conversion time ^{*1} (operation at PCLKC = 50 MHz)	0.52 (0.26)*2		_	μs	Sampling in 13 states	
		0.40 (0.14) ^{*2}			μs	Sampling in 7 states VCC = AVCC0 = 3.0 to 3.6 V $3.0 \text{ V} \leq \text{VREFH0} \leq$ AVCC0	
	Offset error	Offset error					—
	Full-scale error	—	±1.0	±2.5	LSB	—	
	Absolute accuracy		—	±2.0	±4.5	LSB	—
	DNL differential nonlinear	DNL differential nonlinearity error					—
	INL integral nonlinearity e	error	_	±1.0	±2.5	LSB	—
High-precision normal-speed channels (AN003, AN004, AN011 to	Conversion time ^{*1} (Operation at PCLKC = 50 MHz)	0.92 (0.66)*2	_	_	μs	Sampling in 33 states	
AN013)	Offset error	—	±1.0	±2.5	LSB	—	
	Full-scale error	—	±1.0	±2.5	LSB	—	
	Absolute accuracy		_	±2.0	±4.5	LSB	—
	DNL differential nonlinear	ity error	—	±0.5	±1.5	LSB	—
	INL integral nonlinearity e	error	_	±1.0	±2.5	LSB	—
Normal-precision normal-speed channels (AN016)	Conversion time ^{*1} (Operation at PCLKC = 50 MHz)	Permissible signal source impedance Max. = 1 kΩ	0.92 (0.66)*2	_	_	μs	Sampling in 33 states
	Offset error		—	±1.0	±5.5	LSB	—
	Full-scale error		—	±1.0	±5.5	LSB	—
	Absolute accuracy	—	±2.0	±7.5	LSB	—	
	DNL differential nonlinear	ity error	-	±0.5	±4.5	LSB	—
	INL integral nonlinearity e	error	—	±1.0	±5.5	LSB	—

These specification values apply when there is no access to the external memory during A/D conversion. If access occurs during Note: A/D conversion, values might not fall within the indicated ranges.

The use of PORT0 as digital outputs is not allowed when the 12-Bit A/D converter is used. The characteristics apply when AVCC0, AVSS0, VREFH0, VREFL0, and 12-bit A/D converter input voltage are stable. Note 1. The conversion time includes the sampling and comparison times. The number of sampling states is indicated for the test conditions.

Note 2. Values in parentheses indicate the sampling time.

Table 2.35 A/D internal reference voltage characteristics

Parameter	Min	Тур	Max	Unit	Test conditions
A/D internal reference voltage	1.13	1.18	1.23	V	—
Sampling time	4.15	—	_	μs	—





Figure 2.47 Illustration of ADC12 characteristic terms

Absolute accuracy

Absolute accuracy is the difference between output code based on the theoretical A/D conversion characteristics, and the actual A/D conversion result. When measuring absolute accuracy, the voltage at the midpoint of the width of the analog input voltage (1-LSB width), which can meet the expectation of outputting an equal code based on the theoretical A/D conversion characteristics, is used as an analog input voltage. For example, if 12-bit resolution is used and the reference voltage VREFH0 = 3.072 V, then the 1-LSB width becomes 0.75 mV, and 0 mV, 0.75 mV, and 1.5 mV are used as the analog input voltages. If the analog input voltage is 6 mV, an absolute accuracy of \pm 5 LSB means that the actual A/D conversion result is in the range of 0x003 to 0x00D, though an output code of 0x008 can be expected from the theoretical A/D conversion characteristics.

Integral nonlinearity error (INL)

Integral nonlinearity error is the maximum deviation between the ideal line when the measured offset and full-scale errors are zeroed, and the actual output code.

Differential nonlinearity error (DNL)

Differential nonlinearity error is the difference between the 1-LSB width based on the ideal A/D conversion characteristics and the width of the actual output code.

Offset error

Offset error is the difference between the transition point of the ideal first output code and the actual first output code.



Full-scale error

Full-scale error is the difference between the transition point of the ideal last output code and the actual last output code.

2.6 DAC12 Characteristics

Table 2.36D/A conversion characteristics

Parameter	Min	Тур	Мах	Unit	Test conditions
Resolution	_	_	12	Bits	—
Without output amplifier	•		•	•	
Absolute accuracy	_	—	±24	LSB	Resistive load 2 M Ω
INL	—	±2.0	±8.0	LSB	Resistive load 2 M Ω
DNL	—	±1.0	±2.0	LSB	—
Output impedance	—	8.5	—	kΩ	—
Conversion time	—	—	3	μs	Resistive load 2 M Ω , Capacitive load 20 pF
Output voltage range	0	—	VREFH	V	—
With output amplifier			·		
INL	_	±2.0	±4.0	LSB	—
DNL	—	±1.0	±2.0	LSB	—
Conversion time	—	—	4.0	μs	—
Resistive load	5	-	—	kΩ	—
Capacitive load	_	-	50	pF	—
Output voltage range	0.2	—	VREFH – 0.2	V	—

2.7 OSC Stop Detect Characteristics

Table 2.37 Oscillation stop detection circuit characteristics

Parameter	Symbol	Min	Тур	Мах	Unit	Test conditions
Detection time	t _{dr}	—	_	1	ms	Figure 2.48



Figure 2.48 Oscillation stop detection timing



2.8 POR and LVD Characteristics

Table 2.38	Power-on reset circuit and voltage detection circuit characteristics (1)
------------	--

Parameter			Symbol	Min	Тур	Max	Un it	Test conditions	
Voltage detection level	Power-on reset (POR)	DPSBYCR.DEEPCUT[1:0] = 00b or 01b.	V _{POR}	2.5	2.6	2.7	V	Figure 2.49	
		DPSBYCR.DEEPCUT[1:0] = 11b.		1.8	2.25	2.7	1		
	Voltage detection	V _{det0_1}	2.84	2.94	3.04	1	Figure 2.50		
		V _{det0_2}	2.77	2.87	2.97	1			
			V _{det0_3}	2.70	2.80	2.90	1		
	Voltage detection	V _{det1_1}	2.89	2.99	3.09		Figure 2.51		
		V _{det1_2}	2.82	2.92	3.02	1			
			V _{det1_3}	2.75	2.85	2.95			
	Voltage detection	Voltage detection circuit (LVD2)				3.09		Figure 2.52	
		V _{det2_2}	2.82	2.92	3.02				
			V _{det2_3}	2.75	2.85	2.95	1		
Internal reset time	Power-on reset tin	ne	t _{POR}	—	4.5	—	ms	Figure 2.49	
	LVD0 reset time	t _{LVD0}	—	0.51	_]	Figure 2.50		
	LVD1 reset time	t _{LVD1}	—	0.38	_]	Figure 2.51		
	LVD2 reset time	t _{LVD2}	—	0.38	_]	Figure 2.52		
Minimum VCC down time ^{*1}				200	_	_	μs	Figure 2.49, Figure 2.50	
Response delay				_	_	200	μs	Figure 2.50 to Figure 2.52	
LVD operation stabilization time (after LVD is enabled)			t _{d(E-A)}	—	—	10	μs	Figure 2.51,	
Hysteresis width (LVD1 and LVD2)			V _{LVH}	-	70	-	m V	Figure 2.52	

Note 1. The minimum VCC down time indicates the time when VCC is below the minimum value of voltage detection levels V_{POR} , V_{det0} , V_{det1} , and V_{det2} for POR and LVD.



Figure 2.49 Power-on reset timing













Figure 2.52 Voltage detection circuit timing (V_{det2})

2.9 VBATT Characteristics

Table 2.39 Battery backup function characteristics

Conditions: VCC = AVCC0 = VCC_USB = 2.7 to 3.6 V, 2.7 ≤ VREFH0/VREFH ≤ AVCC0, VBATT = 1.65 to 3.6 V^{*1}

Parameter	Symbol	Min	Тур	Мах	Unit	Test conditions		
Voltage level for switching to battery backup	V _{DETBATT}	2.50	2.60	2.70	V	Figure 2.53		
Lower-limit VBATT voltage for power supply switching caused by VCC voltage drop	VBATTSW	2.70	—	_	V			
VCC-off period for starting power supply switching	t _{voffbatt}	200	_	_	μs			
VBATT low voltage detection level	V _{battldet}	1.8	1.9	2.0	V	Figure 2.54		
Minimum VBATT down time	tBATTOFF	200	_	_	μs			
Response delay	t _{BATTdet}	_	_	200	μs			
VBATT monitor operation stabilization time (after VBATTMNSELR.VBATTMNSEL is changed to 1)	t _{d(E-A)}	-	_	20	μs			
VBATT current increase (when VBATTMNSELR.VBATTMNSEL is 1 compared to the case that VBATTMNSELR.VBATTMNSEL is 0)	IVBATTSEL	_	140	350	nA			

Note: The VCC-off period for starting power supply switching indicates the period in which VCC is below the minimum value of the voltage level for switching to battery backup (V_{DETBATT}).

Note 1. Low CL crystal cannot be used below VBATT = 1.8 V.









Figure 2.54 Battery backup function characteristics

Flash Memory Characteristics 2.10

2.10.1 Code Flash Memory Characteristics

Table 2.40 Code flash memory characteristics (1 of 2)

			FCLK =	4 MHz		20 MHz ≤	FCLK ≤	50 MHz		T 4
Parameter		Symbol	Min	Typ*6	Max	Min	Typ ^{*6}	Max	Unit	Test conditions
Programming time	128-byte	t _{P128}	_	0.75	13.2	—	0.34	6.0	ms	
N _{PEC} ≤ 100 times	8-KB	t _{P8K}	_	49	176	—	22	80	ms	
	32-KB	t _{P32K}	_	194	704	—	88	320	ms	
Programming time N _{PEC} > 100 times	128-byte	t _{P128}	_	0.91	15.8	—	0.41	7.2	ms	
	8-KB	t _{P8K}	_	60	212	—	27	96	ms	
	32-KB	t _{P32K}	_	234	848	—	106	384	ms	
Erasure time	8-KB	t _{E8K}	_	78	216	—	43	120	ms	
N _{PEC} ≤ 100 times	32-KB	t _{E32K}	_	283	864	—	157	480	ms	
Erasure time	8-KB	t _{E8K}	_	94	260	—	52	144	ms	
N _{PEC} > 100 times	32-KB	t _{E32K}	_	341	1040	—	189	576	ms	
Reprogramming/erasure cycle ^{*4}		N _{PEC}	10000*1	_	_	10000 ^{*1}	_	_	Times	



Table 2.40 Code flash memory characteristics (2 of 2)

Conditions: Program or erase: FCLK = 4 to 50 MHz Read: FCLK \leq 50 MHz

		FCLK =	$K = 4 \text{ MHz} \qquad 20 \text{ MHz} \le \text{FCLK} \le 50 \text{ MHz}$		50 MHz		Test		
Parameter	Symbol	Min	Typ*6	Max	Min	Typ ^{*6}	Мах	Unit	conditions
Suspend delay during programming	t _{SPD}	_	—	264	—	_	120	μs	
Programming resume time	t _{PRT}	_	—	110	—	_	50	μs	
First suspend delay during erasure in suspend priority mode	t _{SESD1}	_	—	216	_	_	120	μs	
Second suspend delay during erasure in suspend priority mode	t _{SESD2}	_	—	1.7	_	_	1.7	ms	
Suspend delay during erasure in erasure priority mode	t _{SEED}	_	—	1.7	_	_	1.7	ms	
First erasing resume time during erasure in suspend priority mode ^{*5}	t _{REST1}	_	_	1.7	_	_	1.7	ms	
Second erasing resume time during erasure in suspend priority mode	t _{REST2}	_	—	144	_	_	80	μs	
Erasing resume time during erasure in erasure priority mode	t _{REET}	_	_	144	—	_	80	μs	
Forced stop command	t _{FD}	_	—	32	—	_	20	μs	
Data hold time ^{*2}	t _{DRP}	10 ^{*2 *3}	—		10 ^{*2 *3}	—	—	Years	

Note 1. This is the minimum number of times to guarantee all the characteristics after reprogramming. The guaranteed range is from 1 to the minimum value.

Note 2. This indicates the minimum value of the characteristic when reprogramming is performed within the specified range.

Note 3. This result is obtained from reliability testing.

Note 4. The reprogram/erase cycle is the number of erasures for each block. When the reprogram/erase cycle is n times (n = 10,000), erasing can be performed n times for each block. For example, when 128-byte programming is performed 64 times for different addresses in 8-KB blocks, and then the entire block is erased, the reprogram/erase cycle is counted as one. However, programming the same address several times as one erasure is not enabled. Overwriting is prohibited.

Note 5. Time for resumption includes time for reapplying the erasing pulse (up to one full pulse) that was cut off at the time of suspension.

Note 6. The reference value at VCC = 3.3V and room temperature.



RA4E1 Datasheet



Figure 2.55 Suspension and forced stop timing for flash memory programming and erasure

2.10.2 Data Flash Memory Characteristics

Table 2.41 Data flash memory characteristics (1 of 2)

Conditions: Program or erase: FCLK = 4 to 50 MHz Read: FCLK \leq 50 MHz

			FCLK = 4	MHz		20 MHz ≤ F	CLK ≤ 5	0 MHz		Test
Parameter		Symbol	Min	Typ*6	Max	Min	Typ ^{*6}	Max	Unit	
Programming time	4-byte	t _{DP4}	—	0.36	3.8	—	0.16	1.7	ms	
	8-byte	t _{DP8}	—	0.38	4.0	—	0.17	1.8		
	16-byte	t _{DP16}	—	0.42	4.5	—	0.19	2.0		
Erasure time	64-byte	t _{DE64}	—	3.1	18	—	1.7	10	ms	
	128-byte	t _{DE128}	—	4.7	27	—	2.6	15		
	256-byte	t _{DE256}	—	8.9	50	—	4.9	28		
Blank check time	4-byte	t _{DBC4}	_	_	84	—	_	30	μs	
Reprogramming/erasure cycle ^{*1}		N _{DPEC}	125000 ^{*2}	—	—	125000 ^{*2}	_	—	_	
Suspend delay during programming	4-byte	t _{DSPD}	—	—	264	—	_	120	μs	
	8-byte		—	—	264	—	—	120		
	16-byte		—	—	264	—	—	120		
Programming resume time		t _{DPRT}	—	—	110	—		50	μs	
First suspend delay during erasure in	64-byte	t _{DSESD1}	_	—	216	—	—	120	μs	
suspend priority mode	128-byte		—	—	216	<u> </u>	—	120		
	256-byte		—	—	216	—	—	120		



Table 2.41 Data flash memory characteristics (2 of 2)

Conditions: Program or erase: FCLK = 4 to 50 MHz Read: FCLK \leq 50 MHz

			FCLK = 4	MHz		20 MHz ≤ F	CLK ≤ 5	0 MHz		Test
Parameter	Parameter		Min	Typ*6	Max	Min	Typ ^{*6}	Max	Unit	
Second suspend delay during erasure in suspend priority mode	64-byte	t _{DSESD2}	—	—	300	—	—	300	μs	
	128-byte		—	—	390	—	—	390		
	256-byte		_	—	570	—	—	570		
Suspend delay during erasing in erasure	64-byte	t _{DSEED}	_	—	300	—	_	300	μs	
priority mode	128-byte		_	—	390	—	_	390		
	256-byte		_	—	570	—	_	570		
First erasing resume time during erasure in priority mode ^{*5}	suspend	t _{DREST1}	_	—	300	_	_	300	μs	
Second erasing resume time during erasur suspend priority mode	e in	t _{DREST2}	—	—	126	—	_	70	μs	
Erasing resume time during erasure in erasure priority mode		t _{DREET}	_	—	126	_	_	70	μs	
Forced stop command		t _{FD}	_	_	32	_	_	20	μs	
Data hold time ^{*3}		t _{DRP}	10 ^{*3 *4}	—	—	10 ^{*3 *4}	—	—	Year	

Note 1. The reprogram/erase cycle is the number of erasures for each block. When the reprogram/erase cycle is n times (n = 125,000), erasing can be performed n times for each block. For example, when 4-byte programming is performed 16 times for different addresses in 64-byte blocks, and then the entire block is erased, the reprogram/erase cycle is counted as one. However, programming the same address several times as one erasure is not enabled. Overwriting is prohibited.

Note 2. This is the minimum number of times to guarantee all the characteristics after reprogramming. The guaranteed range is from 1 to the minimum value.

Note 3. This indicates the minimum value of the characteristic when reprogramming is performed within the specified range.

Note 4. This result is obtained from reliability testing.

Note 5. Time for resumption includes time for reapplying the erasing pulse (up to one full pulse) that was cut off at the time of suspension.

Note 6. The reference value at VCC = 3.3 V and room temperature.

2.10.3 Option Setting Memory Characteristics

Table 2.42Option setting memory characteristics

Conditions: Program: FCLK = 4 to 50 MHz
Read: FCLK ≤ 50 MHz

		FCLK = 4	MHz		20 MHz ≤ FCLK ≤ 50 MHz		0 MHz		
Parameter	Symbol	Min	Typ ^{*4}	Max	Min	Typ ^{*4}	Max	Unit	Test conditions
Programming time N _{OPC} ≤ 100 times	t _{OP}	_	83	309	_	45	162	ms	
Programming time N _{OPC} > 100 times	t _{OP}	_	100	371	—	55	195	ms	
Reprogramming cycle	N _{OPC}	20000 ^{*1}	_	_	20000 ^{*1}	_	_	Times	
Data hold time ^{*2}	t _{DRP}	10 ^{*2 *3}	_	—	10 ^{*2 *3}	_	_	Years	

Note 1. This is the minimum number of times to guarantee all the characteristics after reprogramming. The guaranteed range is from 1 to the minimum value.

Note 2. This indicates the minimum value of the characteristic when reprogramming is performed within the specified range.

Note 3. This result is obtained from reliability testing.

Note 4. The reference value at VCC = 3.3 V and room temperature.



2.11 Boundary Scan

 Table 2.43
 Boundary scan characteristics

Parameter	Symbol	Min	Тур	Max	Unit	Test conditions	
TCK clock cycle time	t _{TCKcyc}	100	-	—	ns	Figure 2.56	
TCK clock high pulse width	t _{тскн}	45	_	—	ns		
TCK clock low pulse width	t _{TCKL}	45	_	—	ns		
TCK clock rise time	t _{TCKr}	—	_	5	ns		
TCK clock fall time	t _{TCKf}	—	_	5	ns	-	
TMS setup time	t _{TMSS}	20	_	—	ns	Figure 2.57	
TMS hold time	t _{TMSH}	20	_	—	ns		
TDI setup time	t _{TDIS}	20	_	—	ns		
TDI hold time	t _{TDIH}	20	_	—	ns	-	
TDO data delay	t _{TDOD}	—	_	40	ns		
Boundary scan circuit startup time ^{*1}	T _{BSSTUP}	t _{RESWP}	—	—	—	Figure 2.58	

Note 1. Boundary scan does not function until the power-on reset becomes negative.



Figure 2.56 Boundary scan TCK timing



Figure 2.57 Boundary scan input/output timing





Figure 2.58 Boundary scan circuit startup timing

2.12 Joint Test Action Group (JTAG)

Table 2.44 JTAG

Parameter	Symbol	Min	Тур	Мах	Unit	Test conditions	
TCK clock cycle time	t _{TCKcyc}	40	—	—	ns	Figure 2.59	
TCK clock high pulse width	t _{TCKH}	15	_	_	ns		
TCK clock low pulse width	t _{TCKL}	15	_	_	ns		
TCK clock rise time	t _{TCKr}	_	—	5	ns		
TCK clock fall time	t _{TCKf}	_	_	5	ns	-	
TMS setup time	t _{TMSS}	8	_	_	ns	Figure 2.60	
TMS hold time	t _{TMSH}	8	_	_	ns		
TDI setup time	t _{TDIS}	8	_	_	ns	-	
TDI hold time	t _{TDIH}	8	—	—	ns		
TDO data delay time	t _{TDOD}	—	—	20	ns		









Figure 2.60 JTAG input/output timing

2.13 Serial Wire Debug (SWD)

Table 2.45 SWD

Parameter	Symbol	Min	Тур	Max	Unit	Test conditions	
SWCLK clock cycle time	t _{SWCKcyc}	40	-	—	ns	Figure 2.61	
SWCLK clock high pulse width	t _{SWCKH}	15	_	_	ns		
SWCLK clock low pulse width	t _{SWCKL}	15	—	_	ns		
SWCLK clock rise time	t _{SWCKr}	_	—	5	ns		
SWCLK clock fall time	t _{SWCKf}	—	—	5	ns		
SWDIO setup time	t _{SWDS}	8	—	_	ns	Figure 2.62	
SWDIO hold time	t _{SWDH}	8	-	—	ns		
SWDIO data delay time	t _{SWDD}	2	—	28	ns		









Figure 2.62 SWD input/output timing



Appendix 1. Port States in Each Processing Mode

				Deep Software	After Deep Software Standby mode is canceled (return to startup mode)		
Function	Pin function	Reset	· · · · · · · · · · · · · · · · · · ·		IOKEEP = 0	IOKEEP = 1 ^{*1}	
Mode	MD	Pull-up	Keep-O	Кеер	Hi-Z	Кеер	
JTAG	TCK/TMS/TDI	Pull-up	Кеер-О	Кеер	Hi-Z	Кеер	
	TDO	output	Кеер-О	Кеер	TDO output	Кеер	
IRQ	IRQx	Hi-Z	Keep-O ^{*2}	Кеер	Hi-Z	Кеер	
	IRQx-DS	Hi-Z	Keep-O ^{*2}	Keep ^{*3}	Hi-Z	Кеер	
AGT	AGTIOn	Hi-Z	Keep-O ^{*2}	Кеер	Hi-Z	Кеер	
	AGTIOn (n=1,3)	Hi-Z	Keep-O ^{*2}	Keep ^{*3}	Hi-Z	Кеер	
SCI	RXD0	Hi-Z	Keep-O ^{*2}	Кеер	Hi-Z	Кеер	
IIC	SCLn/SDAn	Hi-Z	Keep-O ^{*2}	Кеер	Hi-Z	Кеер	
USBFS	USB_OVRCURx	Hi-Z	Keep-O ^{*2}	Кеер	Hi-Z	Кеер	
	USB_OVRCURx-DS/ USB_VBUS	Hi-Z	Keep-O ^{*2}	Keep ^{*3}	Hi-Z	Кеер	
	USB_DP/USB_DM	Hi-Z	Keep-O ^{*4}	Keep ^{*3}	Hi-Z	Кеер	
RTC	RTCICx	Hi-Z	Keep-O ^{*2}	Keep ^{*3}	Hi-Z	Кеер	
	RTCOUT	Hi-Z	[RTCOUT selected] RTCOUT output	Кеер	Hi-Z	Кеер	
CLKOUT	CLKOUT	Hi-Z	[CLKOUT selected] CLKOUT output	Кеер	Hi-Z	Кеер	
DAC	DAn	Hi-Z	[DAn output (DAOE = 1)] D/A output retained	Кеер	Hi-Z	Кеер	
Others	_	Hi-Z	Кеер-О	Кеер	Hi-Z	Кеер	

Note: H: High-level

L: Low-level

Hi-Z: High-impedance

Keep-O: Output pins retain their previous values. Input pins go to high-impedance.

Keep: Pin states are retained during periods in Software Standby mode.

Note 1. Retains the I/O port state until the DPSBYCR.IOKEEP bit is cleared to 0.

Note 2. Input is enabled if the pin is specified as the Software Standby canceling source while it is used as an external interrupt pin.

Note 3. Input is enabled if the pin is specified as the Deep Software Standby canceling source.

Note 4. Input is enabled while the pin is used as an input pin.



Appendix 2. Package Dimensions

Information on the latest version of the package dimensions or mountings is displayed in "Packages" on the Renesas Electronics Corporation website.







Figure A2.2 QFN 48-pin



Appendix 3. I/O Registers

This appendix describes I/O register address and access cycles by function.

3.1 Peripheral Base Addresses

This section provides the base addresses for peripherals described in this manual. Table A3.1 shows the name, description, and the base address of each peripheral.

RMPU Reness Memory Protection Unit 0x4000_0000 TZF TustZone Filter 0x4000_0E00 SRAM SRAM Control 0x4000_3000 BUS BUS Control 0x4000_3000 DMAC0 Direct memory access controller 0 0x4000_5000 DMAC1 Direct memory access controller 1 0x4000_5000 DMAC2 Direct memory access controller 2 0x4000_5000 DMAC3 Direct memory access controller 3 0x4000_5100 DMAC4 Direct memory access controller 5 0x4000_5100 DMAC5 Direct memory access controller 6 0x4000_5100 DMAC6 Direct memory access controller 7 0x4000_5100 DMAC7 Direct memory access controller 7 0x4000_5400 DMAC7 Direct memory access controller 7 0x4000_5400 DMAC Data Transfer Controller 0x4000_6000 CPU Data Transfer Controller 0x4000_6000 CPU Data Transfer Controller 0x4000_6000 CPU System Control 0x4001_E000 PORT0 Port 0 Control Registers 0x4008_0	Name	Description	Base address
SRAMSRAM Control0x4000_2000BUSBUS Control0x4000_3000DMAC0Direct memory access controller 00x4000_5000DMAC1Direct memory access controller 10x4000_5040DMAC2Direct memory access controller 20x4000_5080DMAC3Direct memory access controller 30x4000_5100DMAC4Direct memory access controller 40x4000_5100DMAC5Direct memory access controller 60x4000_5180DMAC6Direct memory access controller 70x4000_5100DMAC6Direct memory access controller 70x4000_5100DMAC6Direct memory access controller 70x4000_5100DMAC6DMAC6 Module Activation0x4000_5100DMAC7Direct memory access controller 70x4000_5200DTCData Transfer Controller0x4000_6000ICUInterrupt Controller0x4000_6000CPSCUCPU System Security Control Unit0x400_1600PSCUCPU System Security Control Unit0x400_1600SYSCSystem Control0x4008_0000PORT0Port1 Control Registers0x4008_0000PORT1Port1 Control Registers0x4008_0000PORT2Port 2 Control Registers0x4008_0000PORT3Port 3 Control Registers0x4008_000PORT4Port 4 Control Registers0x4008_000PORT5Port 1 Control Registers0x4008_000PORT6Port 1 Control Registers0x4008_000PORT5Port 5 Control Registers0x4008_000PORT4<	RMPU	Renesas Memory Protection Unit	0x4000_0000
BUSBUS Control0x400_3000DMAC0Direct memory access controller 00x4000_5000DMAC1Direct memory access controller 10x4000_5040DMAC2Direct memory access controller 20x4000_5080DMAC3Direct memory access controller 30x4000_5100DMAC4Direct memory access controller 40x4000_5100DMAC4Direct memory access controller 40x4000_5100DMAC4Direct memory access controller 40x4000_5100DMAC4Direct memory access controller 40x4000_5100DMAC4Direct memory access controller 70x4000_5100DMAC4Direct memory access controller 70x4000_5100DMAC7Direct memory access controller 70x4000_5200DTCData transfer Controller0x4000_5200DTCData transfer Controller0x4000_5200CPSCUCPU System Security Control Unit0x4000_1800DBGDebug Function0x4000_1800PGSCUCPU System Security Control Unit0x4000_1800SYSCSystem Control0x4001_1800PGR14Port 1 Control Registers0x4008_000PORT3Port 2 Control Registers0x4008_000PORT4Port 4 Control Registers0x4008_000PGR5Pm Pin Function Control Register0x4008_000PGR5Pm Pin Function Control Register0x4008_000PGR5Pm Pin Function Control Register0x4008_300RCCEvent Link Controller0x4008_300RCTRealtime Clock0x4008_300 <td>TZF</td> <td>TrustZone Filter</td> <td>0x4000_0E00</td>	TZF	TrustZone Filter	0x4000_0E00
DMAC0Direct memory access controller 00x4000_5000DMAC1Direct memory access controller 10x4000_5040DMAC2Direct memory access controller 20x4000_5080DMAC3Direct memory access controller 30x4000_5000DMAC4Direct memory access controller 40x4000_5100DMAC5Direct memory access controller 50x4000_5180DMAC6Direct memory access controller 70x4000_5180DMAC6Direct memory access controller 70x4000_5200DMADMAC Module Activation0x4000_5200DTCData Transfer Controller0x4000_500DTCData Transfer Controller0x4000_6000CPSCUCPU System Security Control Unit0x4000_6000DBGDebug Function0x4000_1200PGCAHEFlash Cache0x4001_1000PCACHEFlash Cathe0x4000_1200PORT0Port 0 Control Registers0x4008_000PORT1Port 1 Control Registers0x4008_000PORT2Port 2 Control Registers0x4008_000PORT4Port 4 Control Registers0x4008_000PORT5Port 3 Control Registers0x4008_000PORT4Port 4 Control Registers0x4008_000PORT5Port 3 Control Registers0x4008_000PORT4Port 4 Control Registers0x4008_000PORT4Port 4 Control Registers0x4008_000PORT5Port 1 Control Registers0x4008_3000PORT4Port 4 Control Registers0x4008_3000PORT5Port 1 Control	SRAM	SRAM Control	0x4000_2000
DMAC1Direct memory access controller 10x4000_5040DMAC2Direct memory access controller 20x4000_5080DMAC3Direct memory access controller 30x4000_5100DMAC4Direct memory access controller 40x4000_5100DMAC5Direct memory access controller 50x4000_5100DMAC6Direct memory access controller 60x4000_5100DMAC7Direct memory access controller 70x4000_5100DMAC7Direct memory access controller 70x4000_5100DMAC7Direct memory access controller 70x4000_5100DMACDMAC Module Activation0x4000_5200DTCData Transfer Controller0x4000_6000CPSUCPU System Security Control Unit0x4000_6000DBGDebug Function0x4001_1000SYSCSystem Control0x4001_1000SYSCSystem Control0x4008_0000PORT1Port 1 Control Registers0x4008_0000PORT2Port 2 Control Registers0x4008_000PORT3Port 3 Control Registers0x4008_000PORT4Port 4 Control Registers0x4008_000PORT5Port 3 Control Registers0x4008_000PORT6Port 4 Control Registers0x4008_000PORT5Port 3 Control Registers0x4008_000PORT6Port 4 Control Registers0x4008_000PORT5Port 4 Control Registers0x4008_000PORT6Port 4 Control Registers0x4008_300PORT5Port 5 Control Registers0x4008_300PORT6R	BUS	BUS Control	0x4000_3000
DMAC2Direct memory access controller 20x4000_5080DMAC3Direct memory access controller 30x4000_5100DMAC4Direct memory access controller 50x4000_5140DMAC5Direct memory access controller 60x4000_5180DMAC6Direct memory access controller 70x4000_5100DMAC7Direct memory access controller 70x4000_5200DMADMAC Module Activation0x4000_5000DTCData Transfer Controller0x4000_5000ICUInterrupt Controller0x4000_6000CPSCUCPU System Security Control Unit0x4000_6000DBGDebug Function0x4001_1000PORT0Port 0 Control Registers0x4000_000PORT1Port 0 Control Registers0x4000_0000PORT2Port 1 Control Registers0x4000_000PORT3Port 2 Control Registers0x4008_000PORT4Port 4 Control Registers0x4008_000PORT5Port 5 Control Registers0x4008_000PORT5Port 5 Control Registers0x4008_000PORT4Realtime Clock0x4008_000PORT5Port 4 Control Registers0x4008_000PORT4Realtime Clock0x4008_000PORT5Port 5 Control Registers0x4008_300PORT4Natchdog Timer0x4008_300PORT5Port 3 Control Registers0x4008_300PORT4Realtime Clock0x4008_300PORT5Port 4 Control Registers0x4008_300PORT4Natchdog Timer0x4008_300PORT5	DMAC0	Direct memory access controller 0	0x4000_5000
DMAC3Direct memory access controller 30x4000_50C0DMAC4Direct memory access controller 40x4000_5100DMAC5Direct memory access controller 50x4000_5140DMAC6Direct memory access controller 60x4000_5180DMAC7Direct memory access controller 70x4000_5100DMADMAC Module Activation0x4000_5200DTCData Transfer Controller0x4000_6000ICUInterrupt Controller0x4000_6000CPSCUCPU System Security Control Unit0x4000_8000DBGDebug Function0x4000_16000FCACHEFlash Cache0x4001_1600PORT0Port 0 Control Registers0x4000_16000PORT1Port 0 Control Registers0x4008_0000PORT2Port 2 Control Registers0x4008_0000PORT3Port 3 Control Registers0x4008_0060PORT4Port 4 Control Registers0x4008_000PFSPort 5 Control Registers0x4008_000PFSPort 9 Control Registers0x4008_000PORT5Port 5 Control Registers0x4008_000PORT4Port 6 Control Registers0x4008_000PFSPort 9 Control Registers0x4008_000PORT5Port 5 Control Registers0x4008_200RTCRealtime Clock0x4008_300MDTIndependent Watchdog Timer0x4008_300MDTIndependent Watchdog Timer0x4008_3400CACClock Frequency Accuracy Measurement Circuit0x4008_4000POEGPort Output Enable Module for G	DMAC1	Direct memory access controller 1	0x4000_5040
DMAC4Direct memory access controller 40x4000_5100DMAC5Direct memory access controller 50x4000_5140DMAC6Direct memory access controller 60x4000_5180DMAC7Direct memory access controller 70x4000_5200DMADMAC Module Activation0x4000_5200DTCData Transfer Controller0x4000_6000ICUInterrupt Controller0x4000_6000CPSCUCPU System Security Control Unit0x4000_18000DBGDebug Function0x4001_1000SYSCSystem Control0x4001_1000SYSCSystem Control0x4001_1000PORT0Port 0 Control Registers0x4008_000PORT2Port 2 Control Registers0x4008_000PORT3Port 3 Control Registers0x4008_0080PORT4Port 4 Control Registers0x4008_0080PORT5Port 5 Control Registers0x4008_000PORT6Realtime Clock0x4008_3000INDTIndependent Watchdog Timer0x4008_3000WDTValchdog Timer0x4008_3000MDTValchdog Timer	DMAC2	Direct memory access controller 2	0x4000_5080
DMAC5Direct memory access controller 50x4000_5140DMAC6Direct memory access controller 60x4000_5180DMAC7Direct memory access controller 70x4000_51C0DMADMAC Module Activation0x4000_5200DTCData Transfer Controller0x4000_6000ICUInterrupt Controller0x4000_6000CPSCUCPU System Security Control Unit0x4000_8000DBGDebug Function0x400_18000FCACHEFlash Cache0x4001_1000SYSCSystem Control0x4001_1000PORT0Port 0 Control Registers0x4008_0000PORT1Port 1 Control Registers0x4008_0000PORT2Port 2 Control Registers0x4008_0000PORT3Port 3 Control Registers0x4008_0000PORT4Port 4 Control Registers0x4008_0000PORT5Port 5 Control Registers0x4008_0000PORT5Port 5 Control Registers0x4008_0000PORT5Port 5 Control Registers0x4008_0000PICTIndependent Watchdog Timer0x4008_000RTCRealtime Clock0x4008_2000RTCRealtime Clock0x4008_3000INDTIndependent Watchdog Timer0x4008_3000MDTWatchdog Timer0x4008_3600MDTNedule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4008_000USBFSUSB 2.0 FS Module0x4009_000	DMAC3	Direct memory access controller 3	0x4000_50C0
DMAC6Direct memory access controller 60x400_5180DMAC7Direct memory access controller 70x400_5200DMADMAC Module Activation0x400_5200DTCData Transfer Controller0x400_6000ICUInterrupt Controller0x400_6000CPSCUCPU System Security Control Unit0x400_18000DBGDebug Function0x400_18000FCACHEFlash Cache0x400_1000SYSCSystem Control0x400_1000PORT0Port 0 Control Registers0x4008_000PORT1Port 1 Control Registers0x4008_000PORT2Port 2 Control Registers0x4008_0040PORT3Port 3 Control Registers0x4008_0040PORT4Port 4 Control Registers0x4008_0040PORT5Port 5 Control Registers0x4008_0040PORT5Port 5 Control Registers0x4008_0040PFSPm Pin Function Control Register0x4008_0040PFSPm Pin Function Control Register0x4008_0040PFSPort 1 Link Control Register0x4008_0040PFSPort 4 Control Registers0x4008_0040PFSPint 1 Link Control Register0x4008_000ELCEvent Link Control Register0x4008_3000INDTIndependent Watchdog Timer0x4008_300WDTWatchdog Timer0x4008_300CACClock Frequency Accuracy Measurement Circuit0x4008_400MDTModule Stop Control A, B, C, D0x4008_400POEGPort Output Enable Module for GPT0x4008_4	DMAC4	Direct memory access controller 4	0x4000_5100
DMAC7Direct memory access controller 70x400_51C0DMADMAC Module Activation0x400_5200DTCData Transfer Controller0x400_6000ICUInterrupt Controller0x400_6000CPSCUCPU System Security Control Unit0x400_18000DBGDebug Function0x400_11000FCACHEFlash Cache0x400_1000SYSCSystem Control0x400_1000PORT0Port 0 Control Registers0x4008_0000PORT1Port 1 Control Registers0x4008_0040PORT2Port 2 Control Registers0x4008_0040PORT3Port 3 Control Registers0x4008_0040PORT4Port 4 Control Registers0x4008_0040PORT5Port 5 Control Registers0x4008_0040PORT5Port 5 Control Registers0x4008_0040PICTRealtime Clock0x4008_0040INDTIndependent Watchdog Timer0x4008_3000WDTWatchdog Timer0x4008_3000CACClock Frequency Accuracy Measurement Circuit0x4008_4000POEGPort Output Enable Module for GPT0x4008_4000VBFSUSB 2.0 FS Module0x4008_000	DMAC5	Direct memory access controller 5	0x4000_5140
DMADMAC Module Activation0x4000_5200DTCData Transfer Controller0x4000_5400ICUInterrupt Controller0x4000_6000CPSCUCPU System Security Control Unit0x4000_8000DBGDebug Function0x400_18000FCACHEFlash Cache0x400_11200SYSCSystem Control Registers0x4008_0000PORT0Port 0 Control Registers0x4008_0000PORT2Port 2 Control Registers0x4008_0040PORT3Port 3 Control Registers0x4008_0060PORT4Port 4 Control Registers0x4008_0080PORT5Port 5 Control Registers0x4008_0000PIRT5Port 5 Control Registers0x4008_000PIRT5Port 5 Control Registers0x4008_000PIRT5Port 6 Control Registers0x4008_000PIRT5Port 6 Control Registers0x4008_000PIRT5Port 6 Control Registers0x4008_000PIRT5Port 6 Control Registers0x4008_3000PIRT6Realtime Clock0x4008_3000RTCRealtime Clock0x4008_3000IWDTIndependent Watchdog Timer0x4008_300WDTWatchdog Timer0x4008_300CACClock Frequency Accuracy Measurement Circuit0x4008_3000MSTPModule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4008_000USBFSUSB 2.0 FS Module0x4008_000	DMAC6	Direct memory access controller 6	0x4000_5180
DTCData Transfer Controller0x400_5400ICUInterrupt Controller0x4000_6000CPSCUCPU System Security Control Unit0x4000_8000DBGDebug Function0x400_18000FCACHEFlash Cache0x400_1C100SYSCSystem Control0x4001_E000PORT0Port 0 Control Registers0x4008_0000PORT1Port 1 Control Registers0x4008_0000PORT2Port 2 Control Registers0x4008_0040PORT3Port 3 Control Registers0x4008_0040PORT4Port 4 Control Registers0x4008_0040PORT5Port 5 Control Registers0x4008_0040PORT6Port 5 Control Registers0x4008_0040PORT5Port 5 Control Registers0x4008_0040PORT5Port 5 Control Registers0x4008_0040PISPmn Pin Function Control Register0x4008_0040PICELCEvent Link Control Register0x4008_000RTCRealtime Clock0x4008_3000IWDTIndependent Watchdog Timer0x4008_3000WDTWatchdog Timer0x4008_3000CACClock Frequency Accuracy Measurement Circuit0x4008_3000MSTPModule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4009_0000	DMAC7	Direct memory access controller 7	0x4000_51C0
ICUInterrupt Controller0x4000_6000CPSCUCPU System Security Control Unit0x4000_8000DBGDebug Function0x400_1B000FCACHEFlash Cache0x400_1C100SYSCSystem Control0x4001_E000PORT0Port 0 Control Registers0x4008_0000PORT1Port 1 Control Registers0x4008_0020PORT2Port 2 Control Registers0x4008_0040PORT3Port 3 Control Registers0x4008_0060PORT4Port 4 Control Registers0x4008_0080PORT5Port 5 Control Registers0x4008_0080PORT6Port 6 Control Registers0x4008_0080PORT5Port 5 Control Registers0x4008_000PSPmn Pin Function Control Register0x4008_000FLCEvent Link Controller0x4008_000RTCRealtime Clock0x4008_3000IWDTIndependent Watchdog Timer0x4008_3000WDTWatchdog Timer0x4008_3400CACClock Frequency Accuracy Measurement Circuit0x4008_3600MSTPModule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4008_4000USBFSUSB 2.0 FS Module0x4009_000	DMA	DMAC Module Activation	0x4000_5200
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FCACHEFlash Cache0x400_1C100SYSCSystem Control0x4001_E000PORT0Port 0 Control Registers0x4008_0000PORT1Port 1 Control Registers0x4008_0020PORT2Port 2 Control Registers0x4008_0040PORT3Port 3 Control Registers0x4008_0060PORT4Port 4 Control Registers0x4008_0080PORT5Port 5 Control Registers0x4008_0080PORT5Port 5 Control Registers0x4008_0080ELCEvent Link Control Register0x4008_0000RTCRealtime Clock0x4008_3000IWDTIndependent Watchdog Timer0x4008_3200WDTWatchdog Timer0x4008_3600CACClock Frequency Accuracy Measurement Circuit0x4008_3600POEGPort Output Enable Module for GPT0x4008_A000USBFSUSB 2.0 FS Module0x4008_000	CPSCU	CPU System Security Control Unit	0x4000_8000
SYSCSystem Control0x4001_E000PORT0Port 0 Control Registers0x4008_0000PORT1Port 1 Control Registers0x4008_0020PORT2Port 2 Control Registers0x4008_0040PORT3Port 3 Control Registers0x4008_0060PORT4Port 4 Control Registers0x4008_0080PORT5Port 5 Control Registers0x4008_00A0PFSPmn Pin Function Control Register0x4008_00A0ELCEvent Link Controller0x4008_2000RTCRealtime Clock0x4008_3000IWDTIndependent Watchdog Timer0x4008_3200WDTWatchdog Timer0x4008_3600CACClock Frequency Accuracy Measurement Circuit0x4008_4000POEGPort Output Enable Module for GPT0x4008_A000USBFSUSB 2.0 FS Module0x4009_0000	DBG	Debug Function	0x400_1B000
PORT0Port 0 Control Registers0x4008_0000PORT1Port 1 Control Registers0x4008_0020PORT2Port 2 Control Registers0x4008_0040PORT3Port 3 Control Registers0x4008_0060PORT4Port 4 Control Registers0x4008_0080PORT5Port 5 Control Registers0x4008_00A0PSSPmn Pin Function Control Register0x4008_00A0ELCEvent Link Control Register0x4008_2000RTCRealtime Clock0x4008_3000IWDTIndependent Watchdog Timer0x4008_3200VDTWatchdog Timer0x4008_3200CACClock Frequency Accuracy Measurement Circuit0x4008_3600MSTPModule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4008_A000USBFSUSB 2.0 FS Module0x4009_0000	FCACHE	Flash Cache	0x400_1C100
PORT1Port 1 Control Registers0x4008_0020PORT2Port 2 Control Registers0x4008_0040PORT3Port 3 Control Registers0x4008_0060PORT4Port 4 Control Registers0x4008_0080PORT5Port 5 Control Registers0x4008_00A0PFSPrm Pin Function Control Register0x4008_0080ELCEvent Link Controller0x4008_2000RTCRealtime Clock0x4008_3000IWDTIndependent Watchdog Timer0x4008_3200WDTVatchdog Timer0x4008_3400CACClock Frequency Accuracy Measurement Circuit0x4008_4000POEGPort Output Enable Module for GPT0x4008_A000USBFSUSB 2.0 FS Module0x4009_0000	SYSC	System Control	0x4001_E000
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PORT4Port 4 Control Registers0x4008_0080PORT5Port 5 Control Registers0x4008_00A0PFSPmn Pin Function Control Register0x4008_0800ELCEvent Link Controller0x4008_2000RTCRealtime Clock0x4008_3000IWDTIndependent Watchdog Timer0x4008_3200WDTWatchdog Timer0x4008_3400CACClock Frequency Accuracy Measurement Circuit0x4008_3600MSTPModule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4008_A000USBFSUSB 2.0 FS Module0x4009_0000	PORT2	Port 2 Control Registers	0x4008_0040
PORT5Port 5 Control Registers0x4008_00A0PFSPmn Pin Function Control Register0x4008_0800ELCEvent Link Controller0x4008_2000RTCRealtime Clock0x4008_3000IWDTIndependent Watchdog Timer0x4008_3200WDTWatchdog Timer0x4008_3400CACClock Frequency Accuracy Measurement Circuit0x4008_3600MSTPModule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4008_A000USBFSUSB 2.0 FS Module0x4009_0000	PORT3	Port 3 Control Registers	0x4008_0060
PFSPmn Pin Function Control Register0x4008_0800ELCEvent Link Controller0x4008_2000RTCRealtime Clock0x4008_3000IWDTIndependent Watchdog Timer0x4008_3200WDTWatchdog Timer0x4008_3400CACClock Frequency Accuracy Measurement Circuit0x4008_3600MSTPModule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4008_A000USBFSUSB 2.0 FS Module0x4009_0000	PORT4	Port 4 Control Registers	0x4008_0080
ELCEvent Link Controller0x4008_2000RTCRealtime Clock0x4008_3000IWDTIndependent Watchdog Timer0x4008_3200WDTWatchdog Timer0x4008_3400CACClock Frequency Accuracy Measurement Circuit0x4008_3600MSTPModule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4008_A000USBFSUSB 2.0 FS Module0x4009_0000	PORT5	Port 5 Control Registers	0x4008_00A0
RTCRealtime Clock0x4008_3000IWDTIndependent Watchdog Timer0x4008_3200WDTWatchdog Timer0x4008_3400CACClock Frequency Accuracy Measurement Circuit0x4008_3600MSTPModule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4008_A000USBFSUSB 2.0 FS Module0x4009_0000	PFS	Pmn Pin Function Control Register	0x4008_0800
IWDTIndependent Watchdog Timer0x4008_3200WDTWatchdog Timer0x4008_3400CACClock Frequency Accuracy Measurement Circuit0x4008_3600MSTPModule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4008_A000USB S.0 FS Module0x4009_0000	ELC	Event Link Controller	0x4008_2000
WDTWatchdog Timer0x4008_3400CACClock Frequency Accuracy Measurement Circuit0x4008_3600MSTPModule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4008_A000USBFSUSB 2.0 FS Module0x4009_0000	RTC	Realtime Clock	0x4008_3000
CACClock Frequency Accuracy Measurement Circuit0x4008_3600MSTPModule Stop Control A, B, C, D0x4008_4000POEGPort Output Enable Module for GPT0x4008_A000USBFSUSB 2.0 FS Module0x4009_0000	IWDT	Independent Watchdog Timer	0x4008_3200
MSTP Module Stop Control A, B, C, D 0x4008_4000 POEG Port Output Enable Module for GPT 0x4008_A000 USBFS USB 2.0 FS Module 0x4009_0000	WDT	Watchdog Timer	0x4008_3400
POEG Port Output Enable Module for GPT 0x4008_A000 USBFS USB 2.0 FS Module 0x4009_0000	CAC	Clock Frequency Accuracy Measurement Circuit	0x4008_3600
USBFS USB 2.0 FS Module 0x4009_0000	MSTP	Module Stop Control A, B, C, D	0x4008_4000
	POEG	Port Output Enable Module for GPT	0x4008_A000
IIC0 Inter-Integrated Circuit 0 0x4009_F000	USBFS	USB 2.0 FS Module	0x4009_0000
	IIC0	Inter-Integrated Circuit 0	0x4009_F000

 Table A3.1
 Peripheral base address (1 of 2)



Name	Description	Base address
IIC0WU	Inter-Integrated Circuit 0 Wake-up Unit	0x4009_F014
CAN0	CAN0 Module	0x400A_8000
PSCU	Peripheral Security Control Unit	0x400E_0000
AGT0	Low Power Asynchronous General purpose Timer 0	0x400E_8000
AGT1	Low Power Asynchronous General purpose Timer 1	0x400E_8100
AGT2	Low Power Asynchronous General purpose Timer 2	0x400E_8200
AGT3	Low Power Asynchronous General purpose Timer 3	0x400E_8300
AGT5	Low Power Asynchronous General purpose Timer 5	0x400E_8500
CRC	CRC Calculator	0x4010_8000
DOC	Data Operation Circuit	0x4010_9000
SCI0	Serial Communication Interface 0	0x4011_8000
SCI3	Serial Communication Interface 3	0x4011_8300
SCI4	Serial Communication Interface 4	0x4011_8400
SCI9	Serial Communication Interface 9	0x4011_8900
SPI0	Serial Peripheral Interface 0	0x4011_A000
SCE9	Secure Cryptographic Engine	0x4016_1000
GPT321	General PWM 32-Bit Timer 1	0x4016_9100
GPT322	General PWM 32-Bit Timer 2	0x4016_9200
GPT164	General PWM 16-Bit Timer 4	0x4016_9400
GPT165	General PWM 16-Bit Timer 5	0x4016_9500
ADC120	12bit A/D Converter 0	0x4017_0000
DAC12	12-bit D/A converter	0x4017_1000
FLAD	Data Flash	0x407F_C000
FACI	Flash Application Command Interface	0x407F_E000
QSPI	Quad-SPI	0x6400_0000

Table A3.1 Peripheral base address (2 of 2)

Note: Name = Peripheral name

Description = Peripheral functionality

Base address = Lowest reserved address or address used by the peripheral

3.2 Access Cycles

This section provides access cycle information for the I/O registers described in this manual.

- Registers are grouped by associated module.
- The number of access cycles indicates the number of cycles based on the specified reference clock.
- In the internal I/O area, reserved addresses that are not allocated to registers must not be accessed, otherwise operations cannot be guaranteed.
- The number of I/O access cycles depends on bus cycles of the internal peripheral bus, divided clock synchronization cycles, and wait cycles of each module. Divided clock synchronization cycles differ depending on the frequency ratio between ICLK and PCLK.
- When the frequency of ICLK is equal to that of PCLK, the number of divided clock synchronization cycles is always constant.
- When the frequency of ICLK is greater than that of PCLK, at least 1 PCLK cycle is added to the number of divided clock synchronization cycles.
- The number of write access cycles indicates the number of cycles obtained by non-bufferable write access.



Note: This applies to the number of cycles when access from the CPU does not conflict with the instruction fetching to the external memory or bus access from other bus masters such as DTC or DMAC.

			Number of access cycles								
	Address		ICLK = PC	CLK	ICLK > PCL	-K*1					
Peripherals	From	То	Read	Write	Read	Write	Cycle Unit	Related function			
RMPU, TZF, SRAM, BUS, DMACn, DMA, DTC, ICU	0x4000_0000	0x4000_6FFF	2	2	2	2	ICLK	Renesas Memory Protection Unit, TrustZone Filter, SRAM Control, Direct memory access controller n, DMAC Module Activation, DTC Control Register, Interrupt Controller			
CPSCU, DBG, FCACHE	0x4000_8000	0x4001_CFFF	4	3	4	3	ICLK	CPU System Security Control Unit, Debug Function, Flash Cache			
SYSC	0x4001_E000	0x4001_E3FF	5	4	5	4	ICLK	System Control			
SYSC	0x4001_E400	0x4001_E5FF	9	8	5 to 8	5 to 8	PCLKB	System Control			
PORTn, PFS	0x4008_0000	0x4008_0FFF	5	4	2 to 5	2 to 4	PCLKB	Port n Control Registers, Pmn Pin Function Control Register			
ELC, RTC, IWDT, WDT, CAC	0x4008_2000	0x4008_3FFF	5	4	3 to 5	2 to 4	PCLKB	Event Link Controller, Realtime Clock, Independent Watchdog Timer, Watchdog Timer, Clock Frequency Accuracy Measurement Circuit			
MSTP	0x4008_4000	0x4008_4FFF	5	4	2 to 5	2 to 4	PCLKB	Module Stop Control			
POEG	0x4008_A000	0x4008_AFFF	5	4	3 to 5	2 to 4	PCLKB	Port Output Enable Module for GPT			
USBFS	0x4009_0000	0x4009_03FF	6	5	3 to 6	3 to 5	PCLKB	USB 2.0 FS Module			
USBFS	0x4009_0400	0x4009_04FF	4	3	1 to 4	1 to 3	PCLKB	USB 2.0 FS Module			
IICn, IIC0WU	0x4009_2000	0x4009_FFFF	5	4	2 to 5	2 to 4	PCLKB	Inter-Integrated Circuit n, Inter-Integrated Circuit 0 Wake-up Unit			
CANn	0x400A_8000	0x400A_9FFF	5	4	2 to 5	2 to 4	PCLKB	CANn Module			
PSCU	0x400E_0000	0x400E_0FFF	5	4	2 to 5	2 to 4	PCLKB	Peripheral Security Control Unit			
AGTn	0x400E_8000	0x400E_8FFF	7	4	5 to 7	2 to 4	PCLKB	Low Power Asynchronous General purpose Timer n			
CRC, DOC	0x4010_8000	0x4010_9FFF	5	4	2 to 5	2 to 4	PCLKA	CRC Calculator, Data Operation Circuit			
SCIn	0x4011_8000	0x4011_8FFF	5 ^{*2}	4*2	2 to 5 ^{*2}	2 to 4 ^{*2}	PCLKA	Serial Communication Interface n			
SPIn	0x4011_A000	0x4011_AFFF	5 ^{*3}	4 ^{*3}	2 to 5 ^{*3}	2 to 4 ^{*3}	PCLKA	Serial Peripheral Interface n			
SCE9	0x4016_1000	0x4016_1FFF	6	4	3 to 6	2 to 4	PCLKA	Secure Cryptographic Engine			
GPT32n, GPT16n, GPT_OPS	0x4016_9000	0x4016_9FFF	7	4	4 to 7	2 to 4	PCLKA	General PWM 32-Bit Timer n, General PWM 16-Bit Timer n, Output Phase Switching Controller			
ADC12n, DAC12	0x4017_0000	0x4017_2FFF	5	4	2 to 5	2 to 4	PCLKA	12bit A/D Converter n, 12-bit D/A converter			

Table A3.2Access cycles (1 of 3)



Table A3.2Access cycles (2 of 3)

			Number of access cycles						
	Address		ICLK = PCLK	CLK ICLK > PCLK ^{*1}			Cycle		
Peripherals	From	То	Read	Write	Read	Write	Unit	Related function	
QSPI	0x6400_0000	0x6400_000F	5	14 to *4	2 to 5	14 to *4	PCLKA	Quad-SPI	
QSPI	0x6400_0010	0x6400_0013	25 to *4	6 to *4	25 to *4	5 to *4	PCLKA	Quad-SPI	
QSPI	0x6400_0014	0x6400_0037	5	14 to *4	2 to 5	14 to *4	PCLKA	Quad-SPI	
QSPI	0x6400_0804	0x6400_0807	4	3	1 to 4	1 to 3	PCLKA	Quad-SPI	

Table A3.2Access cycles (3 of 3)

			Number of a	f access cycles					
	Address		ICLK = FCLK	(ICLK > FCLK ^{*1} Cycle				
Peripherals	From	То	Read	Write	Read	Write	Unit	Related function	
FLAD, FACI	0x407F_C000	0x407F_EFFF	3	3	2 to 3	2 to 3	FCLK	Data Flash, Flash Application Command Interface	

Note 1. If the number of PCLK or FCLK cycles is non-integer (for example 1.5), the minimum value is without the decimal point, and the maximum value is rounded up to the decimal point. For example, 1.5 to 2.5 is 1 to 3.

Note 2. When accessing a 16-bit register (FTDRHL, FRDRHL, FCR, FDR, LSR, and CDR), access is 2 cycles more than the value shown in Table A3.2. When accessing an 8-bit register (including FTDRH, FTDRL, FRDRH, and FRDRL), the access cycles are as shown in Table A3.2.

Note 3. When accessing the 32-bit register (SPDR), access is 2 cycles more than the value in Table A3.2. When accessing an 8-bit or 16-bit register (SPDR_HA), the access cycles are as shown in Table A3.2.

Note 4. The access cycles depend on the QSPI bus cycles.



Appendix 4. Related Documents

Component	Document Type	Description
Microcontrollers	Data sheet	Features, overview, and electrical characteristics of the MCU
	User's Manual: Hardware	MCU specifications such as pin assignments, memory maps, peripheral functions, electrical characteristics, timing diagrams, and operation descriptions
	Application Notes	Technical notes, board design guidelines, and software migration information
	Technical Update (TU)	Preliminary reports on product specifications such as restriction and errata
Software	User's Manual: Software	Command set, API reference and programming information
	Application Notes	Project files, guidelines for software programming, and application examples to develop embedded software applications
Tools & Kits, Solutions	User's Manual: Development Tools	User's manuals and quick start guides for developing embedded software applications with Software Packages, Development Kits, Starter Kits, Promotion Kits, Product Examples, and Application Examples
	Quick Start Guide	
	Application Notes	Project files, guidelines for software programming, and application examples to develop embedded software applications



Revision History

Revision 1.00 — September 15, 2021

First edition, issued

Revision 1.10 — February 4, 2022

1. Overview:

- Added the introduction to 1.1 Function Outline.
- Removed the sentence on brushless DC motors from GPT functional description in Table 1.7 Timers.
- Added Table 1.11 I/O ports to 1.1 Function Outline.
- Fixed the note 1 in Figure 1.1 Block diagram.
- Fixed the row of QSPI in Table 1.13 Function Comparison.
- Added the row of I/O ports to Table 1.13 Function Comparison.
- Fixed the note 2 in Table 1.13 Function Comparison.

Revision 1.30 — June 6, 2025

1. Overview:

• Updated Figure 1.2 Part numbering scheme.



General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Precaution against Electrostatic Discharge (ESD)

A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power is supplied until the power is supplied until the power reaches the level at which resetting is specified.

3. Input of signal during power-off state

Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

4. Handling of unused pins

Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

5. Clock signals

After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

6. Voltage application waveform at input pin

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between V_{IL} (Max.) and V_{IH} (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between V_{IL} (Max.) and V_{IH} (Min.).

7. Prohibition of access to reserved addresses

Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.

8. Differences between products

Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

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